



# STIC Search Report

## EIC 1700

STIC Database Tracking Number: 119734

**TO: Dawn Garrett**  
**Location: REM 5C75**  
**Art Unit : 1774**  
**April 20, 2004**

**Case Serial Number: 10/625096**

**From: Barba Koroma**  
**Location: EIC 1700**  
**REM EO4 A30**  
**Phone: 571 272 2546**

**barba.koroma@uspto.gov**

### Search Notes

Examiner Garrett,

Please find attached results of the search you requested. Various components of the claimed invention as spelt out in the claims were searched in multiple databases. For your convenience, titles of hits have been listed to help you peruse the results set quickly. This is followed by a detailed printout of records. Please let me know if you have any questions.

Thanks.

Access DB# 119734**SEARCH REQUEST FORM**

Scientific and Technical Information Center

Requester's Full Name: DAWN GARRETT Examiner #: 76107 Date: 4/19/2004  
Art Unit: 1774 Phone Number: 272-1523 Serial Number: 10/625,096  
Mail Box and Bldg/Room Location: Reese 5C75 Results Format Preferred (circle): PAPER DISK E-MAIL

If more than one search is submitted, please prioritize searches in order of need.

\*\*\*\*\*

Please provide a detailed statement of the search topic, and describe as specifically as possible the subject matter to be searched. Include the elected species or structures, keywords, synonyms, acronyms, and registry numbers, and combine with the concept or utility of the invention. Define any terms that may have a special meaning. Give examples or relevant citations, authors, etc. if known. Please attach a copy of the cover sheet, pertinent claims, and abstract.

Title of Invention: Metallic complexes covalently bonded to Conjugated Polymers and Electronic Devices Containing such compounds  
Inventors (please provide full names): Norman Heron, Howard Simmons, Daniel Lecloux, Frank Ucker +

Earliest Priority Filing Date: 7/30/2002

\*For Sequence Searches Only\* Please include all pertinent information (parent, child, divisional, or issued patent numbers) along with the appropriate serial number.

Please search polymeric metal composition (material) recited in claim 1.

Also attached is three pages from specification defining "first-type functional groups" and "first-type inert spacer groups".

\*\*\*\*\*  
**STAFF USE ONLY****Type of Search****Vendors and cost where applicable**

Searcher: _____	NA Sequence (#) _____	STN _____
Searcher Phone #: _____	AA Sequence (#) _____	Dialog _____
Searcher Location: _____	Structure (#) _____	Questel/Orbit _____
Date Searcher Picked Up: _____	Bibliographic _____	Dr.Link _____
Date Completed: _____	Litigation _____	Lexis/Nexis _____
Searcher Prep & Review Time: _____	Fulltext _____	Sequence Systems _____
Clerical Prep Time: _____	Patent Family _____	WWW/Internet _____
Online Time: _____	Other _____	Other (specify) _____

=> file caplus

FILE 'CAPLUS' ENTERED AT 16:30:59 ON 20 APR 2004

USE IS SUBJECT TO THE TERMS OF YOUR STN CUSTOMER AGREEMENT.

PLEASE SEE "HELP USAGETERMS" FOR DETAILS.

COPYRIGHT (C) 2004 AMERICAN CHEMICAL SOCIETY (ACS)

Copyright of the articles to which records in this database refer is held by the publishers listed in the PUBLISHER (PB) field (available for records published or updated in Chemical Abstracts after December 26, 1996), unless otherwise indicated in the original publications. The CA Lexicon is the copyrighted intellectual property of the American Chemical Society and is provided to assist you in searching databases on STN. Any dissemination, distribution, copying, or storing of this information, without the prior written consent of CAS, is strictly prohibited.

FILE COVERS 1907 - 20 Apr 2004 VOL 140 ISS 17

FILE LAST UPDATED: 19 Apr 2004 (20040419/ED)

This file contains CAS Registry Numbers for easy and accurate substance identification.

=> file wpiix

FILE 'WPIIX' ENTERED AT 16:31:02 ON 20 APR 2004

COPYRIGHT (C) 2004 THOMSON DERWENT

FILE LAST UPDATED: 18 APR 2004 <20040418/UP>

MOST RECENT DERWENT UPDATE: 200425 <200425/DW>

DERWENT WORLD PATENTS INDEX SUBSCRIBER FILE, COVERS 1963 TO DATE

>>> FOR A COPY OF THE DERWENT WORLD PATENTS INDEX STN USER GUIDE,  
PLEASE VISIT:  
[http://www.stn-international.de/training\\_center/patents/stn\\_guide.pdf](http://www.stn-international.de/training_center/patents/stn_guide.pdf) <<<

>>> FOR DETAILS OF THE PATENTS COVERED IN CURRENT UPDATES, SEE  
<http://thomsonderwent.com/coverage/latestupdates/> <<<

>>> FOR INFORMATION ON ALL DERWENT WORLD PATENTS INDEX USER  
GUIDES, PLEASE VISIT:  
<http://thomsonderwent.com/support/userguides/> <<<

>>> ADDITIONAL POLYMER INDEXING CODES WILL BE IMPLEMENTED FROM  
DERWENT UPDATE 200403.  
THE TIME RANGE CODE WILL ALSO CHANGE FROM 018 TO 2004.  
SDIS USING THE TIME RANGE CODE WILL NEED TO BE UPDATED.  
FOR FURTHER DETAILS: <http://thomsonderwent.com/chem/polymers/> <<<

>>> NEW! FAST-ALERTING ACCESS TO NEWLY-PUBLISHED PATENT  
DOCUMENTATION NOW AVAILABLE IN DERWENT WORLD PATENTS INDEX  
FIRST VIEW - FILE WPIFV. FREE CONNECT HOUR UNTIL 1 MAY 2004.  
FOR FURTHER DETAILS: <http://www.thomsonderwent.com/dwpifv> <<<

=> file compendex

FILE 'COMPENDEX' ENTERED AT 16:31:09 ON 20 APR 2004

Compendex Compilation and Indexing (C) 2004

Elsevier Engineering Information Inc (EEI). All rights reserved.

Compendex (R) is a registered Trademark of Elsevier Engineering Information Inc.

FILE LAST UPDATED: 13 APR 2004

<20040413/UP>

FILE COVERS 1970 TO DATE.

<<< SIMULTANEOUS LEFT AND RIGHT TRUNCATION AVAILABLE IN  
THE BASIC INDEX >>>

=> d que

L45 41785 SEA FILE=CAPLUS ABB=ON PLU=ON ORGANOMETALLIC  
L46 2633 SEA FILE=CAPLUS ABB=ON PLU=ON ORGANOMETALLICS  
L48 130111 SEA FILE=CAPLUS ABB=ON PLU=ON POLYMER?(L)METAL?  
L50 3617 SEA FILE=CAPLUS ABB=ON PLU=ON (L45 OR L46) AND L48  
L55 2222963 SEA FILE=REGISTRY ABB=ON PLU=ON (M(L)C(L)H)/ELS  
L56 73603 SEA FILE=REGISTRY ABB=ON PLU=ON L55 AND PMS/CI  
L57 70245 SEA FILE=CAPLUS ABB=ON PLU=ON L56  
L58 73658 SEA FILE=CAPLUS ABB=ON PLU=ON L50 OR L57  
L60 2876 SEA FILE=CAPLUS ABB=ON PLU=ON L58 AND DEV/RL  
L62 81 SEA FILE=CAPLUS ABB=ON PLU=ON L60 AND ELECTRONIC?  
L64 44 SEA FILE=CAPLUS ABB=ON PLU=ON L62 AND (IMF OR RCT OR  
PREP)/RL  
L65 44 SEA FILE=CAPLUS ABB=ON PLU=ON L64 AND (METAL? OR ELECTRONIC?  
OR APPARATUS?)  
L69 41 SEA FILE=CAPLUS ABB=ON PLU=ON METAL?(5A)COMPLEX? AND  
POLYMER? AND ELECTRONIC?(5A)DEVICE?  
L71 80 SEA FILE=CAPLUS ABB=ON PLU=ON L65 OR L69  
L75 55 SEA FILE=CAPLUS ABB=ON PLU=ON L71 AND (IMF OR TEM OR  
PREP)/RL  
L77 58 SEA FILE=WPIX ABB=ON PLU=ON METAL?(5A)COMPLEX? AND POLYMER?  
AND ELECTRONIC?(5A)DEVICE?  
L78 7 SEA FILE=COMPENDEX ABB=ON PLU=ON METAL?(5A)COMPLEX? AND  
POLYMER? AND ELECTRONIC?(5A)DEVICE?  
L80 19 SEA FILE=CAPLUS ABB=ON PLU=ON L75 AND (LUMINESC? OR EL OR  
ELECTROLUMINESC? OR FLUORESC? OR PHOSPHORESC?)  
L81 13 SEA FILE=WPIX ABB=ON PLU=ON L77 AND (LUMINESC? OR EL OR  
ELECTROLUMINESC? OR FLUORESC? OR PHOSPHORESC?)  
L82 1 SEA FILE=COMPENDEX ABB=ON PLU=ON L78 AND (LUMINESC? OR EL OR  
ELECTROLUMINESC? OR FLUORESC? OR PHOSPHORESC?)  
L85 29 DUP REM L80 L81 L82 (4 DUPLICATES REMOVED)

=> d ti 1-29 l85

YOU HAVE REQUESTED DATA FROM FILE 'CAPLUS, WPIX' - CONTINUE? (Y)/N:y

L85 ANSWER 1 OF 29 CAPLUS COPYRIGHT 2004 ACS on STN DUPLICATE 1

TI **Metallic complexes** covalently bound to conjugated  
**polymers and electronic devices**

- L85 ANSWER 2 OF 29 CAPLUS COPYRIGHT 2004 ACS on STN  
TI Layer configuration comprising an electron-blocking element
- L85 ANSWER 3 OF 29 CAPLUS COPYRIGHT 2004 ACS on STN  
TI Layer configuration with improved stability to sunlight exposure
- L85 ANSWER 4 OF 29 CAPLUS COPYRIGHT 2004 ACS on STN  
TI Rhodium and iridium complexes
- L85 ANSWER 5 OF 29 CAPLUS COPYRIGHT 2004 ACS on STN DUPLICATE 2  
TI **Polymers** having attached **luminescent metal complexes** and devices made with such **polymers**
- L85 ANSWER 6 OF 29 CAPLUS COPYRIGHT 2004 ACS on STN  
TI **Polymerized** cycloolefins using transition metal catalyst and end product optical articles for **electronic devices**
- L85 ANSWER 7 OF 29 CAPLUS COPYRIGHT 2004 ACS on STN  
TI Process for preparing aromatic **polymers**
- L85 ANSWER 8 OF 29 WPIX COPYRIGHT 2004 THOMSON DERWENT on STN  
TI **Luminescence**-capable material as component in optical device, e.g. **electroluminescent** device, comprises conjugated **polymer** or oligomer and organometallic group covalently bound to **polymer** or oligomer.
- L85 ANSWER 9 OF 29 WPIX COPYRIGHT 2004 THOMSON DERWENT on STN  
TI Organic **electroluminescent** device has hole transport layer and light emitting layer containing host substance and **phosphorescent** dopant.
- L85 ANSWER 10 OF 29 WPIX COPYRIGHT 2004 THOMSON DERWENT on STN  
TI Cleaning tableware for cleaning, sanitizing, and stain removal tableware, involves contacting tableware with aqueous cleaning liquor and bleaching liquor.
- L85 ANSWER 11 OF 29 CAPLUS COPYRIGHT 2004 ACS on STN DUPLICATE 3  
TI **Polymers** having attached **luminescent metal complexes** and devices made with such **polymers**
- L85 ANSWER 12 OF 29 CAPLUS COPYRIGHT 2004 ACS on STN  
TI Emissive multichromophoric systems
- L85 ANSWER 13 OF 29 CAPLUS COPYRIGHT 2004 ACS on STN  
TI Phenazasiline-containing  $\pi$ -conjugated polymers, their manufacture, and their application
- L85 ANSWER 14 OF 29 WPIX COPYRIGHT 2004 THOMSON DERWENT on STN  
TI **Electroluminescent** device, used in liquid crystal displays, includes an **electroluminescent** layer comprising a complex of a rare earth, transition, lanthanide or actinide metal and a non rare earth metal.
- L85 ANSWER 15 OF 29 WPIX COPYRIGHT 2004 THOMSON DERWENT on STN  
TI New conjugated **polymers** especially useful as

**electroluminescent** materials in **polymeric** light-emitting diodes comprise spirobifluorene-type units and fluorene-type units,.

- L85 ANSWER 16 OF 29 WPIX COPYRIGHT 2004 THOMSON DERWENT on STN  
TI Semiconductor light emitting equipment has light-transmitting metalloxane gel layer covering semiconductor light emitting device anchored to the end of the one wiring conductor.
- L85 ANSWER 17 OF 29 CAPLUS COPYRIGHT 2004 ACS on STN  
TI Novel Preparation and Photoelectrochemical Properties of a Tungsten Oxide/Tris(2,2'-bipyridine)ruthenium(II) Complex Composite Film
- L85 ANSWER 18 OF 29 WPIX COPYRIGHT 2004 THOMSON DERWENT on STN  
TI **Electroluminescent** device for use in the development of organic semiconductor employs clay nanocomposite emissive layer spin coated with organic **luminescent** material/clay nanocomposite.
- L85 ANSWER 19 OF 29 CAPLUS COPYRIGHT 2004 ACS on STN  
TI The role of ruthenium and rhenium diimine complexes in conjugated polymers that exhibit interesting opto-**electronic** properties
- L85 ANSWER 20 OF 29 CAPLUS COPYRIGHT 2004 ACS on STN  
TI Multi-component multiphase type polymer material and its use in functional element.
- L85 ANSWER 21 OF 29 CAPLUS COPYRIGHT 2004 ACS on STN  
TI Fabrication of **electronic** devices containing a columnar discotic phase
- L85 ANSWER 22 OF 29 WPIX COPYRIGHT 2004 THOMSON DERWENT on STN  
TI Materials for use in **electroluminescent** devices comprises an organic **complex** of a transition metal, lanthanide or an actinide.
- L85 ANSWER 23 OF 29 WPIX COPYRIGHT 2004 THOMSON DERWENT on STN  
TI Device used for detecting analytes in fluid which includes gases, vapors and liquids.
- L85 ANSWER 24 OF 29 CAPLUS COPYRIGHT 2004 ACS on STN  
TI Synthesis of Polymers with Alternating Organosilanylene and Oligothienylene Units and Their Optical, Conducting, and Hole-Transporting Properties
- L85 ANSWER 25 OF 29 CAPLUS COPYRIGHT 2004 ACS on STN  
TI Synthesis and **electronic** properties of conjugated **polymers** based on rhenium or ruthenium dipyridophenazine complexes
- L85 ANSWER 26 OF 29 CAPLUS COPYRIGHT 2004 ACS on STN  
TI **Electronic** and Light-Emitting Properties of Some Polyimides Based on Bis(2,2':6',2''-terpyridine) Ruthenium(II) Complex
- L85 ANSWER 27 OF 29 CAPLUS COPYRIGHT 2004 ACS on STN  
TI Development of **metal**-containing polymers for optoelectronic applications

L85 ANSWER 28 OF 29 CAPLUS COPYRIGHT 2004 ACS on STN DUPLICATE 4  
 TI  $\pi$ -Conjugated **polymers** bearing electronic and optical functionalities. Preparation, properties and their applications

L85 ANSWER 29 OF 29 WPIX COPYRIGHT 2004 THOMSON DERWENT on STN  
 TI Crown moiety-containing peptide - useful as detector of sodium and potassium ions, **electronic device** material, etc..

=> d all 1-29 l85

YOU HAVE REQUESTED DATA FROM FILE 'CAPLUS, WPIX' - CONTINUE? (Y)/N:y

L85 ANSWER 1 OF 29 CAPLUS COPYRIGHT 2004 ACS on STN DUPLICATE 1  
 AN 2004:143238 CAPLUS  
 DN 140:182406  
 ED Entered STN: 22 Feb 2004  
 TI **Metallic complexes** covalently bound to conjugated **polymers** and **electronic devices**  
 IN Herron, Norman; Lecloux, Daniel David; Simmons, Howard E., III; Uckert, Frank P.  
 PA E. I. Du Pont De Nemours and Company, USA  
 SO PCT Int. Appl., 53 pp.  
 CODEN: PIXXD2  
 DT Patent  
 LA English  
 IC ICM C09K011-06  
 ICS H05B033-14; H01L051-20; H01L051-30; C08G061-02; C08G061-12  
 CC 37-3 (Plastics Manufacture and Processing)  
 Section cross-reference(s): 73, 76

FAN.CNT 1

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
WO 2004015025	A1	20040219	WO 2003-US23690	20030729
W: AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BY, BZ, CA, CH, CN, CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, ES, FI, GB, GD, GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KP, KR, KZ, LC, LK, LR, LS, LT, LU, LV, MA, MD, MG, MK, MN, MW, MX, MZ, NI, NO, NZ, OM, PG, PH, PL, PT, RO, RU, SC, SD, SE, SG, SK, SL, SY, TJ, TM, TN, TR, TT, TZ, UA, UG, UZ, VC, VN, YU, ZA, ZM, ZW, AM, AZ, BY, KG, KZ, MD, RU, TJ RW: GH, GM, KE, LS, MW, MZ, SD, SL, SZ, TZ, UG, ZM, ZW, AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE, IT, LU, MC, NL, PT, RO, SE, SI, SK, TR, BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG				
US 2004072018	A1	20040415	US 2003-625096	20030722
PRAI US 2002-399934P	P	20020730		
AB The <b>polymeric metal complexes</b> comprise <b>metallic</b> (e.g. La, Pt, Ir, Al) complexes covalently bound to conjugated <b>polymers</b> and <b>luminescent</b> materials containing such <b>polymeric metal complexes</b> . The <b>electronic luminescent devices</b> have active layer that includes such <b>polymeric metal complexes</b> . A metal complex of				

IrOH[2-[2,4-(difluorophenyl)isoquinoline]2]2 (prepared from IrCl<sub>3</sub> hydrate and (difluorophenyl)isoquinoline ligand) was prepared, which could be reacted with a copolymer containing fluorenyloxidiazole units.

ST **electroluminescent device conjugated polymer metal complex**

IT **Electroluminescent devices**  
(Pt, Ir, and Al complex with fluorene, fluorenyloxidiazole, and octylcarbazole copolymer for)

IT 660393-98-6P 660393-99-7P 660394-03-6P  
RL: **IMF (Industrial manufacture); PREP (Preparation)**  
(Pt, Ir, and Al complex with fluorene, fluorenyloxidiazole, and octylcarbazole copolymer for)

IT 660393-99-7DP, fluorenyloxidiazole copolymer complex 660394-03-6DP, Ir complex  
RL: **IMF (Industrial manufacture); TEM (Technical or engineered material use); PREP (Preparation); USES (Uses)**  
(Pt, Ir, and Al complex with fluorene, fluorenyloxidiazole, and octylcarbazole copolymer for)

IT 10025-83-9, Iridium trichloride 19493-44-8, 1-Chloroisoquinoline  
RL: **RCT (Reactant); RACT (Reactant or reagent)**  
(Pt, Ir, and Al complex with fluorene, fluorenyloxidiazole, and octylcarbazole copolymer for)

IT 435294-70-5P  
RL: **IMF (Industrial manufacture); RCT (Reactant); PREP (Preparation); RACT (Reactant or reagent)**  
(hydrolysis; Pt, Ir, and Al complex with fluorene, fluorenyloxidiazole, and octylcarbazole copolymer for)

IT 123324-71-0, 4-tert-Butylphenylboronic acid 144025-03-6, 2,4-Difluorophenylboronic acid  
RL: **RCT (Reactant); RACT (Reactant or reagent)**  
(reaction with chloroisoquinoline; Pt, Ir, and Al complex with fluorene, fluorenyloxidiazole, and octylcarbazole copolymer for)

IT 525598-48-5P 660393-97-5P  
RL: **IMF (Industrial manufacture); RCT (Reactant); PREP (Preparation); RACT (Reactant or reagent)**  
(reaction with iridium trichloride; Pt, Ir, and Al complex with fluorene, fluorenyloxidiazole, and octylcarbazole copolymer for)

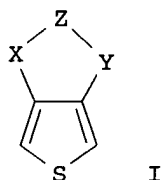
L85 ANSWER 2 OF 29 CAPLUS COPYRIGHT 2004 ACS on STN  
AN 2004:182587 CAPLUS  
DN 140:236722  
ED Entered STN: 05 Mar 2004  
TI Layer configuration comprising an electron-blocking element  
IN Andriessen, Hieronymus  
PA Agfa-Gevaert, Belg.  
SO U.S. Pat. Appl. Publ., 20 pp.  
CODEN: USXXCO  
DT Patent  
LA English  
IC ICM C07D211-02  
NCL 546185000  
CC 38-3 (Plastics Fabrication and Uses)  
Section cross-reference(s): 52, 73, 76  
FAN.CNT 1  
PATENT NO. KIND DATE APPLICATION NO. DATE



```

-----
PI  US 2004044214      A1    20040304      US 2003-638918      20030811
    WO 2004019346      A1    20040304      WO 2003-EP50341     20030729
      W:  AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BY, BZ, CA, CH, CN,
          CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, ES, FI, GB, GD, GE, GH,
          GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KP, KR, KZ, LC, LK, LR,
          LS, LT, LU, LV, MA, MD, MG, MK, MN, MW, MX, MZ, NI, NO, NZ, OM,
          PG, PH, PL, PT, RO, RU, SC, SD, SE, SG, SK, SL, SY, TJ, TM, TN,
          TR, TT, TZ, UA, UG, VC, VN, YU, ZA, ZM, ZW, AM, AZ, BY, KG, KZ,
          MD, RU, TJ, TM
      RW:  GH, GM, KE, LS, MW, MZ, SD, SL, SZ, TZ, UG, ZM, ZW, AT, BE, BG,
          CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE, IT, LU, MC,
          NL, PT, RO, SE, SI, SK, TR, BF, BJ, CF, CG, CI, CM, GA, GN, GQ,
          GW, ML, MR, NE, SN, TD, TG
PRAI EP 2002-102216      A      20020823
      US 2002-409731P      P      20020911
      EP 2003-100327      A      20030213
GI

```



AB Layered structures comprising a nonphotoactive element formed from compds. other than poly(3,4-alkylenedioxythiophene)s and poly(3,4-dialkoxythiophene)s are described in which the structures include a first polymer containing structural units are described by the general formula I (X and Y = independently selected O, S, N-R<sub>1</sub>; Z = -(CH<sub>2</sub>)<sub>m</sub> CR<sub>2</sub>R<sub>3</sub>-(CH<sub>2</sub>)<sub>n</sub>-; R<sub>1</sub> = aryl, C<sub>1</sub>-18 alkyl, or H; R<sub>2</sub> = H or -(CH<sub>2</sub>)<sub>s</sub>-O-(CH<sub>2</sub>)<sub>p</sub>-SO<sub>3</sub>-M<sup>+</sup>; R<sub>3</sub> = -(CH<sub>2</sub>)<sub>s</sub>-O-(CH<sub>2</sub>)<sub>p</sub>-SO<sub>3</sub>-M<sup>+</sup>; M<sup>+</sup> = a cation; m = 0-3; n = 0-3; s = 0-10; and p = 1-18) and a second polymer different from the first polymer and selected from the group consisting of optionally quaternized polyamine-polymers, polysulfo-polymers, polyphosphoric acids and polyphosphoric acid salts, the surface of one side of the element being contiguous with a pos. electrode and the surface on the opposite side of the element being contiguous with a hole-transporting material. The layers are capable of reducing hole-electron recombination at the pos. electrode thereby increasing the efficiency and lifetime of **electronic** devices containing such layered structures. **Electroluminescent** devices, especially light-emitting diodes, transistors, and photovoltaic devices (e.g., solar cells) including the structures are also described.

ST polythiophene deriv layer hole electron recombination control **electronic** device; solar cell polythiophene deriv layer hole electron recombination control; **electroluminescent** device polythiophene deriv layer hole electron recombination control; transistor polythiophene deriv layer hole electron recombination control; photovoltaic device polythiophene deriv layer hole electron recombination control

IT **Electroluminescent** devices

Photoelectric devices

Solar cells

Transistors

(layered structures with polythiophene derivative-containing layers for hole-electron recombination control and **electronic** devices using them)

IT Conducting polymers

(polythiophenes; layered structures with polythiophene derivative-containing layers for hole-electron recombination control and **electronic** devices using them)

IT 667420-85-1P

RL: **BYP (Byproduct); PREP (Preparation)**

(layered structures with polythiophene derivative-containing layers for hole-electron recombination control and **electronic** devices using them)

IT 30619-16-0, Acrylamide-4-vinylpyridine copolymer 50851-57-5,

Poly(styrenesulphonic acid) 667455-83-6, Acrylamide-N-vinylimidazole-4-vinylpyridine copolymer

RL: **DEV (Device component use); POF (Polymer in formulation);**

**USES (Uses)**

(layered structures with polythiophene derivative-containing layers for hole-electron recombination control and **electronic** devices using them)

IT 204444-03-1P

RL: **DEV (Device component use); POF (Polymer in formulation);**

**SPN (Synthetic preparation); PREP (Preparation); USES (Uses)**

(layered structures with polythiophene derivative-containing layers for hole-electron recombination control and **electronic** devices using them)

IT 3132-64-7, Epibromohydrin 58416-04-9

RL: **RCT (Reactant); RACT (Reactant or reagent)**

(layered structures with polythiophene derivative-containing layers for hole-electron recombination control and **electronic** devices using them)

IT 1633-83-6P, Butanesultone 7646-69-7P, Sodium hydride (NaH)

146796-02-3P 146796-14-7P 204444-01-9P 540803-64-3P

RL: **RCT (Reactant); SPN (Synthetic preparation); PREP (Preparation); RACT (Reactant or reagent)**

(layered structures with polythiophene derivative-containing layers for hole-electron recombination control and **electronic** devices using them)

L85 ANSWER 3 OF 29 CAPLUS COPYRIGHT 2004 ACS on STN

AN 2004:182502 CAPLUS

DN 140:236721

ED Entered STN: 05 Mar 2004

TI Layer configuration with improved stability to sunlight exposure

IN Louwet, Frank; Dyck, Geert Van; Loccufier, Johan; Groenendaal, Bert; Andriessen, Hieronymus

PA Agfa-Gevaert, Belg.

SO U.S. Pat. Appl. Publ., 24 pp.

CODEN: USXXCO

DT Patent

LA English

IC ICM B01J031-00

NCL 502159000

CC 38-3 (Plastics Fabrication and Uses)

Section cross-reference(s): 52, 73, 76

FAN.CNT 2

	PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
PI	US 2004043895	A1	20040304	US 2003-642933	20030818
PRAI	EP 2002-102217	A	20020823		
	US 2002-409794P	P	20020911		

OS MARPAT 140:236721

AB Layered structures comprising a layer containing a polymer containing optionally

substituted 3,4-alkylenedioxythiophene structural units, in which the alkoxy groups may be the same or different or together represent an optionally substituted oxy-alkylene-oxy bridge, and a compound selected from the group consisting of polyphosphoric acids, polyphosphoric acid salts, thia-alkanedicarboxylic acids, cyclohexadiene compds. and polyhydroxy-compds. selected from the group consisting of tetronic acid derivs., ortho-dihydroxybenzene compds. with  $\geq 1$  sulfo group, compds. described by the general formula  $\text{HO-CH}_2\text{-CH(OH)-(CH}_2\text{)}_m\text{-S-CH}_2\text{-C(R}_1\text{)(R}_2\text{)-CH}_2\text{-S-(CH}_2\text{)}_n\text{-CH(OH)-CH}_2\text{-OH}$  (I: R<sub>1</sub> and R<sub>2</sub> = independently selected H, -OH, or alkyl; n = 1, 2, or 3; and m = 1, 2 or 3); compds. described by the general formula  $\text{HO-(CH}_2\text{)}_p\text{-S-CH}_2\text{-S-(CH}_2\text{)}_q\text{-OH}$  (p = 2, 3, or 4; q = 2, 3 or 4), compds. hydrolyzable to tetronic acid derivs., compds. hydrolyzable to compds. described by the general formula I; and sulfo-substituted 2-thia-alkyl-benzimidazole compds. The layers are capable of reducing hole-electron recombination at the pos. electrode thereby increasing the efficiency and lifetime of **electronic** devices containing such layered structures. **Electroluminescent** devices, especially light-emitting diodes, transistors, and photovoltaic

devices

(e.g., solar cells) including the structures are also described.

ST polythiophene deriv layer light resistance **electronic** device;  
solar cell polythiophene deriv layer light resistance;  
**electroluminescent** device polythiophene deriv layer light  
resistance; transistor polythiophene deriv layer light resistance;  
photovoltaic device polythiophene deriv layer light resistance

IT Carboxylic acids, uses

RL: DEV (Device component use); USES (Uses)

(dicarboxylic, thiaalkane; layered structures with improved stability  
to sunlight exposure and **electronic** devices using them)

IT **Electroluminescent** devices

Photoelectric devices

Solar cells

Transistors

(layered structures with improved stability to sunlight exposure and  
**electronic** devices using them)

IT Polyphosphates

RL: DEV (Device component use); USES (Uses)

(layered structures with improved stability to sunlight exposure and  
**electronic** devices using them)

IT Polyphosphoric acids

RL: DEV (Device component use); MOA (Modifier or additive use);

USES (Uses)

(layered structures with improved stability to sunlight exposure and

- electronic** devices using them)
- IT Conducting polymers  
(polythiophenes; layered structures with improved stability to sunlight exposure and **electronic** devices using them)
- IT 667420-85-1P  
RL: **BYP (Byproduct); PREP (Preparation)**  
(layered structures with improved stability to sunlight exposure and **electronic** devices using them)
- IT 51-17-2D, Benzimidazole, thiaalkyl derivs. 4971-56-6D, Tetronic acid, derivs. 29797-09-9D, Cyclohexadiene, derivs.  
RL: **DEV (Device component use); USES (Uses)**  
(layered structures with improved stability to sunlight exposure and **electronic** devices using them)
- IT 50851-57-5, Poly(styrene sulphonate)  
RL: **DEV (Device component use); MOA (Modifier or additive use);**  
**POF (Polymer in formulation); USES (Uses)**  
(layered structures with improved stability to sunlight exposure and **electronic** devices using them)
- IT 30619-16-0, Acrylamide-4-vinylpyridine copolymer 126213-51-2, Poly(3,4-ethylenedioxythiophene) 126213-51-2D, Poly(3,4-ethylenedioxythiophene), derivs. 126213-52-3, Poly(3,4-methylenedioxythiophene) 126213-52-3D, Poly(3,4-methylenedioxythiophene), derivs. 150504-14-6, Poly(3,4-propylenedioxythiophene) 150504-14-6D, Poly(3,4-propylenedioxythiophene), derivs. 202927-42-2, Poly(3,4-butylenedioxythiophene) 202927-42-2D, Poly(3,4-butylenedioxythiophene), derivs.  
RL: **DEV (Device component use); POF (Polymer in formulation);**  
**USES (Uses)**  
(layered structures with improved stability to sunlight exposure and **electronic** devices using them)
- IT 204444-03-1P  
RL: **DEV (Device component use); POF (Polymer in formulation);**  
**SPN (Synthetic preparation); PREP (Preparation); USES (Uses)**  
(layered structures with improved stability to sunlight exposure and **electronic** devices using them)
- IT 3132-64-7, Epibromohydrin 58416-04-9  
RL: **RCT (Reactant); RACT (Reactant or reagent)**  
(layered structures with improved stability to sunlight exposure and **electronic** devices using them)
- IT 1633-83-6P, Butanesultone 7646-69-7P, Sodium hydride (NaH) 146796-02-3P 146796-14-7P 204444-01-9P 540803-64-3P  
RL: **RCT (Reactant); SPN (Synthetic preparation); PREP (Preparation); RACT (Reactant or reagent)**  
(layered structures with improved stability to sunlight exposure and **electronic** devices using them)

L85 ANSWER 4 OF 29 CAPLUS COPYRIGHT 2004 ACS on STN

AN 2004:177928 CAPLUS

DN 140:235899

ED Entered STN: 04 Mar 2004

TI Rhodium and iridium complexes

IN Stoessel, Philipp; Bach, Ingrid; Spreitzer, Hubert

PA Covion Organic Semiconductors G.m.b.H., Germany

SO Ger. Offen., 19 pp.

CODEN: GWXXBX

DT Patent

LA German

IC ICM C07F015-00

CC 29-13 (Organometallic and Organometalloidal Compounds)

Section cross-reference(s): 52, 73, 76

FAN.CNT 1

	PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
PI	DE 10238903	A1	20040304	DE 2002-10238903	20020824
	WO 2004026886	A2	20040401	WO 2003-EP9015	20030814

W: CN, JP, KR, US

RW: AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE,

IT, LU, MC, NL, PT, RO, SE, SI, SK, TR

PRAI DE 2002-10238903 A 20020824

AB 5'-Mono-, 5',5''-bis-, and 5,5',5'''-tris-(hetero)aryl-functionalized tris-orthometallated organorhodium and organoiridium compds. are claimed along with a method for their production entailing reaction of an appropriate halogen-functionalized complex with an (hetero)aryl boronic acid or (hetero)aryl boronic acid ester. Mixts. of the **organometallic** compds. with **polymers** are also described. The compds. are described as **phosphorescent** emitters. **Electronic devices**, such as **electroluminescent devices** (where they may be part of the emitting layer), organic integrated circuits, organic field-effect transistors, organic thin-film transistors, solar cells, photovoltaic devices (e.g., organic solar cells and organic photodetectors) and organic solid-state lasers, employing the complexes and mixts. are also described. Thus, fac-tris[2-(2-pyridinyl-κN)(5-bromophenyl)-κC]iridium(III) was reacted with phenylboronic acid to produce fac-tris[2-(2-pyridinyl-κN)[5-(phenyl)phenyl]-κC]iridium(III).

ST iridium hetero aryl functionalized ligand complex prepn **electronic device**; rhodium hetero aryl functionalized ligand complex prepn **electronic device**

IT **Luminescent** substances

(electroluminescent; rhodium complexes and iridium complexes

including (hetero)aryl-functionalized ligands and their preparation and use)

IT **Electroluminescent** devices

Field effect transistors

Integrated circuits

Semiconductor lasers

Solar cells

Thin film transistors

(organic; rhodium complexes and iridium complexes including

(hetero)aryl-functionalized ligands and their preparation and use)

IT **Conducting polymers**(polythiophenes, mixts. with **metal complexes**;rhodium **complexes** and iridium **complexes** including

(hetero)aryl-functionalized ligands and their preparation and use)

IT **Optical detectors****Phosphorescent** substances

Photoelectric devices

(rhodium complexes and iridium complexes including (hetero)aryl-

functionalized ligands and their preparation and use)

IT 25067-59-8, Polyvinylcarbazole 25190-62-9, Poly(1,4-phenylene)

51555-21-6, Polycarbazole 95270-88-5, Polyfluorene 192005-02-0,

9,9'-Spirobi[9H-fluorene] homopolymer  
 RL: DEV (Device component use); USES (Uses)  
 (mixts. with metal complexes; rhodium complexes and iridium complexes including (hetero)aryl-functionalized ligands and their preparation and use)

IT 7440-16-6D, Rhodium, compds. with (hetero)aryl-functionalized ligands  
 RL: DEV (Device component use); USES (Uses)  
 (rhodium complexes and iridium complexes including (hetero)aryl-functionalized ligands and their preparation and use)

IT 667935-05-9P 667935-06-0P 667935-07-1P 667935-08-2P 667935-09-3P  
 667935-10-6P 667935-20-8P  
 RL: DEV (Device component use); IMF (Industrial manufacture); PREP (Preparation); USES (Uses)  
 (rhodium complexes and iridium complexes including (hetero)aryl-functionalized ligands and their preparation and use)

IT 98-80-6, Benzeneboronic acid 1993-03-9, 2-Fluorobenzeneboronic acid 16419-60-6, 2-Methylbenzeneboronic acid 85199-06-0 144025-03-6, 2,4-Difluorobenzeneboronic acid 156545-07-2, 3,5-Difluorobenzeneboronic acid 168267-41-2, 3,4-Difluorobenzeneboronic acid 454454-92-3, fac-Tris[2-(2-pyridinyl- $\kappa$ N)(5-bromophenyl)- $\kappa$ C]iridium(III) 667933-70-2 667935-11-7  
 RL: RCT (Reactant); RACT (Reactant or reagent)  
 (rhodium complexes and iridium complexes including (hetero)aryl-functionalized ligands and their preparation and use)

L85 ANSWER 5 OF 29 CAPLUS COPYRIGHT 2004 ACS on STN DUPLICATE 2  
 AN 2003:609916 CAPLUS  
 DN 139:171082  
 ED Entered STN: 08 Aug 2003  
 TI **Polymers** having attached **luminescent metal complexes** and devices made with such **polymers**  
 IN Fryd, Michael; Grushin, Vladimir; Herron, Norman; Periyasamy, Mookkan; Petrov, Viacheslav A.; Radu, Nora Sabina  
 PA USA  
 SO U.S. Pat. Appl. Publ., 23 pp.  
 CODEN: USXXCO  
 DT Patent  
 LA English  
 IC ICM H05B033-14  
 ICS C09K011-06  
 NCL 428690000; 428917000; 313504000; 257040000; 257103000; 252301350; 252301160  
 CC 73-5 (Optical, Electron, and Mass Spectroscopy and Other Related Properties)  
 Section cross-reference(s): 38, 76  
 FAN.CNT 1

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
US 2003148142	A1	20030807	US 2001-974113	20011009
PRAI US 2001-974113		20011009		

AB Organic **electronic devices** are described which comprise an emitting layer which comprises  $\geq 1$  functionalized **polymer** having a plurality of first-type functional groups, at least a portion of the functional groups being coordinated to  $\geq 1$  **metal** or **metal-containing complex**, or in which the groups have a

charge and are associated with  $\geq 1$  **metal complex** having an opposite charge. The emitting layers may also include organic charge transport materials. Selected **polymer-metal complexes** and salts are also described.

- ST **metal complex polymer salt**  
**electroluminescent device; metal polymer complex electroluminescent device**
- IT Group VIII element compounds  
RL: DEV (Device component use); USES (Uses)  
(Group 10; **metal-polymer complexes** and salts and devices employing them)
- IT Polyanilines  
RL: DEV (Device component use); USES (Uses)  
(charge transport material; **metal-polymer complexes** and salts and devices employing them)
- IT Group VIII element compounds  
RL: DEV (Device component use); USES (Uses)  
(cobalt-group; **metal-polymer complexes** and salts and devices employing them)
- IT **Luminescent substances**  
(**electroluminescent; metal-polymer complexes** and salts and devices employing them)
- IT Group VIII element compounds  
RL: DEV (Device component use); USES (Uses)  
(iron-group; **metal-polymer complexes** and salts and devices employing them)
- IT **Electroluminescent devices**  
(**metal-polymer complexes** and salts and devices employing them)
- IT Group IB element compounds  
Group IIB element compounds  
Group IIIA element compounds  
Group VIIB element compounds  
Rare earth **complexes**  
RL: DEV (Device component use); USES (Uses)  
(**metal-polymer complexes** and salts and devices employing them)
- IT 25067-59-8, Polyvinylcarbazole 58328-31-7 65181-78-4,  
N,N'-Diphenyl-N,N'-bis(3-methylphenyl)-(1,1'-biphenyl)-4,4'-diamine  
70895-80-6, Bis[4-(N,N-diethylamino)-2-methylphenyl](4-methylphenyl)methane  
RL: DEV (Device component use); USES (Uses)  
(charge transport material; **metal-polymer complexes** and salts and devices employing them)
- IT 7439-88-5D, Iridium, compds., reaction products with **polymers**  
7440-04-2D, Osmium, compds., reaction products with **polymers**  
7440-05-3D, Palladium, compds., reaction products with **polymers**  
7440-06-4D, Platinum, compds., reaction products with **polymers**  
7440-16-6D, Rhodium, compds., reaction products with **polymers**  
7440-18-8D, Ruthenium, compds., reaction products with **polymers**  
7440-27-9D, Terbium, compds., reaction products with **polymers**  
7440-30-4D, Thulium, compds., reaction products with **polymers**  
7440-57-5D, Gold, compds., reaction products with **polymers**  
7440-66-6D, Zinc, compds., reaction products with **polymers**  
40231-87-6D, reaction products with **polymers** 176763-58-9D,

reaction products with **polymers** 412040-84-7D, reaction products with **polymers**  
RL: DEV (Device component use); USES (Uses)  
(**metal-polymer complexes** and salts and devices employing them)

IT 126213-51-2, Poly(3,4-ethylenedioxythiophene)  
RL: DEV (Device component use); POF (Polymer in formulation); USES (Uses)  
(**metal-polymer complexes** and salts and devices employing them)

IT 14054-87-6DP, reaction products with **polymers** 14592-81-5DP, reaction products with **polymers** 26284-14-0DP, reaction products with **metal** compds. 26355-01-1DP, 2-Hydroxyethyl methacrylate-methyl methacrylate copolymer, reaction products with **metal** compds. 56315-94-7DP, 2-Hydroxyethyl methacrylate-isobutyl methacrylate copolymer, reaction products with **metal** compds. 66028-15-7DP, 2-(Dimethylamino)ethyl methacrylate-Isobutylmethacrylate copolymer, reaction products with **metal** compds. 72460-28-7DP, 4,4'-Bis(chlorocarbonyl)-2,2'-bipyridine, reaction products with **polymers** and **metal** compds. 190370-38-8DP, reaction products with **polymers** 387859-66-7DP, reaction products with **polymers** 412032-55-4DP, reaction products with electron-transporting compds. and **metal** compds. 412032-56-5DP, reaction products with **polymers** and **metal** compds. 412032-57-6DP, reaction products with electron-transporting compds. and **metal** compds. 412032-58-7DP, reaction products with **metal** compds. 412032-59-8DP, reaction products with **metal** compds. 412032-60-1DP, reaction products with **metal** compds.  
RL: DEV (Device component use); SPN (Synthetic preparation); **PREP** (**Preparation**); USES (Uses)  
(**metal-polymer complexes** and salts and devices employing them)

IT 95-54-5, 1,2-Diaminobenzene, reactions 97-93-8, Triethylaluminum, reactions 694-83-7, 1,2-Diaminocyclohexane 1765-93-1, 4-Fluorophenylboronic acid 2695-37-6, 4-Styrenesulfonic acid sodium salt 3796-23-4 10025-83-9, Iridium trichloride 32503-27-8, Tetrabutylammonium hydrogen sulfate 37942-07-7, 3,5-Di-tert-butyl-2-hydroxybenzaldehyde  
RL: RCT (Reactant); RACT (Reactant or reagent)  
(**metal-polymer complexes** and salts and devices employing them)

IT 37295-36-6P 66028-15-7P, 2-(Dimethylamino)ethyl methacrylate-Isobutylmethacrylate copolymer 103595-82-0P 190370-38-8P 370878-58-3P 387859-66-7P  
RL: RCT (Reactant); SPN (Synthetic preparation); **PREP** (**Preparation**); RACT (Reactant or reagent)  
(**metal-polymer complexes** and salts and devices employing them)

L85 ANSWER 6 OF 29 CAPLUS COPYRIGHT 2004 ACS on STN  
AN 2003:757368 CAPLUS  
DN 139:261652  
ED Entered STN: 26 Sep 2003  
TI **Polymerized** cycloolefins using transition metal catalyst and end product optical articles for **electronic devices**



IN Rhodes, Larry Funderburk; Bell, Andrew; Ravikiran, R.; Fondran, John C.; Jayaraman, Saikumar; Goodall, Brian Leslie; Mimna, Richard A.; Lipian, John-Henry

PA USA

SO U.S. Pat. Appl. Publ., 90 pp., Cont.-in-part of U.S. Ser. No. 196,525.

CODEN: USXXCO

DT Patent

LA English

IC ICM C08F004-44

NCL 526134000; 526308000; 526171000; 526172000

CC 35-3 (Chemistry of Synthetic High Polymers)

Section cross-reference(s): 67, 76

FAN.CNT 2

	PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
	-----	---	----	-----	-----
PI	US 2003181607	A1	20030925	US 2002-271393	20021015
	US 2002052454	A1	20020502	US 1999-412935	19991005
	US 6455650	B2	20020924		
	US 2003023013	A1	20030130	US 2002-196525	20020716
	US 2004048994	A1	20040311	US 2003-464978	20030618
PRAI	US 1998-103120P	P	19981005		
	US 1999-412935	A3	19991005		
	US 2002-196525	A2	20020716		
	US 1998-111590P	P	19981209		
	US 2002-271393	A1	20021015		

OS MARPAT 139:261652

AB The addition **polymerization** of cycloolefins uses a cationic Group 10 **metal complex** and a weakly coordinating anion (WCA), [(R')zM(L')x(L'')y]b[WCA]d, where [(R')zM(L')x(L'')y] is a cation complex where M is a Group 10 transition metal; R' is anionic hydrocarbyl containing ligand; L' is Group 15 neutral electron donor ligand; L'' is a labile neutral electron donor ligand; x = 1 or 2; y = 0, 1, 2, or 3; z = 0 or 1, where the sum of x, y, and z = 4; [WCA] is counter anion complex; and b and d are nos. representing the number of times the cation complex and weakly coordinating counter anion complex are taken to balance the electronic charge on the overall catalyst complex.

ST optical semiconductor device cycloolefin **polymer**; transition **metal complex** catalyst cycloolefin **polymn**; allylpalladium cyclohexylphosphine fluorophenylborate catalyst butylnorbornene ethoxysilylnorbornene **polymn**

IT Polysiloxanes, preparation

RL: IMF (Industrial manufacture); PREP (Preparation)

(block polycycloalkene-; transition **metal complexes**

stabilized by weakly coordinating counterions for catalysts for **polymerization** of cycloolefins)

IT Amines, uses

RL: CAT (Catalyst use); USES (Uses)

(**complexes**; transition **metal complexes**

stabilized by weakly coordinating counterions for catalysts for **polymerization** of cycloolefins)

IT Electroluminescent devices

Electronic packaging materials

Optoelectronic semiconductor **devices**

(cycloolefin **polymers** for packaging of **electronic devices**)

- IT Polysiloxanes, preparation  
 RL: IMF (Industrial manufacture); PREP (Preparation)  
 (di-Me, Me vinyl, vinyl group-terminated, Gelest VMM 010, reaction products with hexylnorbornene and triethoxysilylnorbornene; transition metal complexes stabilized by weakly coordinating counterions for catalysts for polymerization of cycloolefins)
- IT Polysiloxanes, preparation  
 RL: IMF (Industrial manufacture); PREP (Preparation)  
 (di-Me, di-Ph, vinyl group-terminated, Gelest PDV 1625, reaction products with hexylnorbornene and triethoxysilylnorbornene; transition metal complexes stabilized by weakly coordinating counterions for catalysts for polymerization of cycloolefins)
- IT Cycloalkenes  
 RL: IMF (Industrial manufacture); PREP (Preparation)  
 (polymers; transition metal complexes stabilized by weakly coordinating counterions for catalysts for polymerization of cycloolefins)
- IT Polymerization catalysts  
 (transition metal complexes stabilized by weakly coordinating counterions for catalysts for polymerization of cycloolefins)
- IT Platinum-group metal complexes  
 RL: CAT (Catalyst use); USES (Uses)  
 (transition metal complexes stabilized by weakly coordinating counterions for catalysts for polymerization of cycloolefins)
- IT Fluoropolymers, preparation  
 RL: IMF (Industrial manufacture); PREP (Preparation)  
 (transition metal complexes stabilized by weakly coordinating counterions for catalysts for polymerization of cycloolefins)
- IT 116-17-6, Triisopropyl phosphite 432-04-2, Tris(trifluoromethyl)phosphine 554-70-1, Triethylphosphine 585-48-8, 2,6-Di-tert-butylpyridine 594-09-2, Trimethylphosphine 603-34-9, Triphenylamine 603-35-0, Triphenylphosphine, uses 603-36-1, Triphenylstibine 607-01-2, Ethyldiphenylphosphine 672-66-2, Dimethylphenylphosphine 819-19-2, Di-tert-butylphosphine 829-84-5, Dicyclohexylphosphine 855-38-9, Tris(p-methoxyphenyl)phosphine 998-40-3, Tributylphosphine 1017-60-3, Bis[4-methylphenyl]phosphine 1038-95-5, Tri-p-tolylphosphine 1101-41-3, Tetraphenylbiphosphine 1159-54-2, Tris(4-chlorophenyl)phosphine 1259-35-4, Tris(pentafluorophenyl)phosphine 1485-88-7, (2-Methoxyphenyl)methylphenylphosphine 1605-53-4, Diethylphenylphosphine 1663-45-2, 1,2-Bis(diphenylphosphino)ethane 1732-72-5, Dibutylphosphine 1795-31-9, Tris(trimethylsilyl) phosphite 2155-96-6, Diphenylvinylphosphine 2234-97-1, Tripropylphosphine 2622-14-2, Tricyclohexylphosphine 2741-38-0, Allyldiphenylphosphine 2752-19-4, Tri-o-xenyl phosphite 4006-38-6, Diisobutylphosphine 4125-25-1, Triisobutylphosphine 4731-53-7, Tri-n-octylphosphine 4731-65-1, Tris(2-methoxyphenyl)phosphine 5074-71-5, Bis(pentafluorophenyl)phenylphosphine 5518-52-5, Tris(2-furylphosphine 5525-95-1, Diphenyl(pentafluorophenyl)phosphine 6002-34-2, tert-Butyldiphenylphosphine 6163-58-2, Tri-o-tolylphosphine 6224-63-1, Tri-m-tolylphosphine 6372-40-3, Diphenylisopropylphosphine 6372-42-5, Cyclohexyldiphenylphosphine 6372-44-7, Dibutylphenylphosphine 6476-36-4, Triisopropylphosphine 6476-37-5, Dicyclohexylphenylphosphine

7650-88-6, Tricyclopentylphosphine 7650-89-7, Tribenzylphosphine  
 7650-91-1, Benzylidiphenylphosphine 13406-29-6, Tris(p-  
 trifluoromethylphenyl)phosphine 13716-12-6, Tri-tert-butylphosphine  
 14180-51-9, Bis(4-methoxyphenyl)phenylphosphine 15383-58-1,  
 1,2-Bis(diphenylphosphino)propane 15573-38-3,  
 Tris(trimethylsilyl)phosphine 16523-89-0, Triallylphosphine  
 17261-28-8, 2-(Diphenylphosphino)benzoic acid 17586-49-1,  
 Tri-sec-butylphosphine 18437-78-0, Tris(p-fluorophenyl)phosphine  
 23743-26-2, 1,2-Bis(dicyclohexylphosphino)ethane 23897-15-6,  
 Tris(2,4,6-trimethylphenyl)phosphine 24171-89-9, Tris(2-  
 thienyl)phosphine 24850-33-7, Allyltributyltin 26464-99-3,  
 Dimethyl(trimethylsilyl)phosphine 26681-88-9, Divinylphenylphosphine  
 28609-58-7, Tris(phenylthio)stibine 28653-22-7, Trinaphthylphosphine  
 29949-75-5, Diallylphenylphosphine 29949-84-6, Tris(m-  
 methoxyphenyl)phosphine 29949-85-7, Tris(3-chlorophenyl)phosphine  
 31570-04-4, Tris(2,4-di-tert-butylphenyl) phosphite 42491-33-8,  
 tert-Butylbis(trimethylsilyl)phosphine 43077-29-8, Diphenyl-(+)-  
 neomenthylphosphine 53111-20-9, Diphenyl(2-methoxyphenyl)phosphine  
 56522-04-4, Dibenzylphosphine 63995-70-0 76189-55-4 83622-85-9,  
 Tris(3-methoxypropyl)phosphine 85417-41-0, Tris(2,6-  
 dimethoxyphenyl)phosphine 166172-69-6, Bis[3,5-  
 bis(trifluoromethyl)phenyl]phosphine 175136-62-6, Tris[3,5-  
 bis(trifluoromethyl)phenyl]phosphine 193404-80-7 216020-59-6,  
 Bis(2-furyl)phosphine 263878-91-7

RL: CAT (Catalyst use); USES (Uses)

(catalyst ligand; transition metal complexes

stabilized by weakly coordinating counterions for catalysts for  
**polymerization** of cycloolefins)

IT 75-16-1, Methylmagnesium bromide 124-41-4, Sodium methoxide 127-91-3,  
 β-Pinene 139362-04-2

RL: RCT (Reactant); RACT (Reactant or reagent)

(catalyst precursor; transition metal complexes

stabilized by weakly coordinating counterions for catalysts for  
**polymerization** of cycloolefins)

IT 100-42-5D, Styrene, crosslinked polymer

RL: CAT (Catalyst use); USES (Uses)

(catalyst support; transition metal complexes

stabilized by weakly coordinating counterions for catalysts for  
**polymerization** of cycloolefins)

IT 2102-16-1, Hexadeuterocyclopentadiene 25291-17-2, 1H,1H,2H-Perfluoro-1-  
 octene

RL: RCT (Reactant); RACT (Reactant or reagent)

(monomer precursor; transition metal complexes

stabilized by weakly coordinating counterions for catalysts for  
**polymerization** of cycloolefins)

IT 263879-07-8P

RL: IMF (Industrial manufacture); RCT (Reactant); PREP

(Preparation); RACT (Reactant or reagent)

(monomer; transition metal complexes stabilized by

weakly coordinating counterions for catalysts for **polymerization** of  
 cycloolefins)

IT 97-93-8, Triethylaluminum, uses 1295-35-8, Bis(cyclooctadiene)nickel  
 3375-31-3 12012-95-2, Allylpalladium chloride dimer 12107-56-1  
 12145-60-7, (Methallyl)nickel chloride dimer 13965-03-2 14024-61-4,  
 Palladium acetylacetonate 15242-92-9 18987-59-2 28425-04-9

29934-17-6, Bis(tricyclohexylphosphine)palladium dichloride 31989-57-8, Bis(triphenylphosphine)palladium 32216-28-7, Allylplatinum chloride tetramer 33309-88-5 34424-15-2 40691-33-6 42196-31-6, Palladium trifluoroacetate 63936-77-6 63936-85-6, (1,5-Cyclooctadiene)methylpalladium chloride 125475-73-2 135348-57-1, Ferrocenium tetrakis(pentafluorophenyl)borate 141219-72-9, Palladium ethylhexanoate 172418-32-5 263878-78-0 263879-42-1 263879-43-2 263879-44-3

RL: CAT (Catalyst use); USES (Uses)

(transition metal complexes stabilized by weakly coordinating counterions for catalysts for polymerization of cycloolefins)

IT 12013-04-6P, (Allyl)palladium iodide dimer 28016-71-9P 32699-43-7P  
34829-33-9P 58676-44-1P 71035-50-2P 79270-04-5P 119875-93-3P  
125893-61-0P 179803-34-0P 263878-70-2P 263878-71-3P 263878-72-4P  
263878-73-5P 263878-74-6P 263878-75-7P 263878-76-8P 263878-77-9P  
263878-79-1P 263878-80-4P 263905-49-3P 263905-50-6P

RL: CAT (Catalyst use); IMF (Industrial manufacture); PREP (Preparation); USES (Uses)

(transition metal complexes stabilized by weakly coordinating counterions for catalysts for polymerization of cycloolefins)

IT 25038-76-0P, Polynorbornene 25038-78-2P, Polydicyclopentadiene  
26935-77-3P, Poly(5-butyl-2-norbornene) 26935-79-5P,  
Poly(5-hexylnorbornene) 26935-85-3P 29036-48-4P, Poly-5-ethyl-2-norbornene 118777-99-4P 146066-32-2P, Poly(5-triethoxysilyl-2-norbornene) 146066-36-6P 252338-36-6P 252338-37-7P,  
Butylnorbornene-5-triethoxysilylnorbornene copolymer 252338-38-8P  
263878-83-7P 263878-84-8P 263878-85-9P 263878-86-0P 263878-87-1P  
263878-88-2P 263878-89-3P 263878-90-6P 263878-92-8P 263878-94-0P  
263878-96-2P 263878-97-3P 263878-98-4P 263878-99-5P 263879-00-1P  
263879-01-2P 263879-02-3P 263879-03-4P 263879-04-5P 263879-05-6P  
263879-06-7P 263879-08-9P 263879-09-0P 263879-10-3P 263879-11-4P  
263879-12-5P 263880-86-0P 263905-51-7P 263905-52-8P 264133-20-2P

RL: IMF (Industrial manufacture); PREP (Preparation)

(transition metal complexes stabilized by weakly coordinating counterions for catalysts for polymerization of cycloolefins)

IT 199450-09-4 220836-13-5 220836-14-6 220836-19-1 220836-26-0  
220836-29-3 220836-34-0 263880-01-9 263880-02-0 263880-03-1  
263880-04-2 263880-05-3 263880-07-5 263880-09-7 263880-10-0  
263880-12-2 263880-13-3 263880-14-4 263880-15-5 263880-16-6  
263880-18-8 263880-19-9 263880-22-4 263880-24-6 263880-25-7  
263880-28-0 263880-30-4 263880-34-8 263880-36-0 263880-38-2  
263880-40-6 263880-42-8 263880-43-9 263880-45-1 263880-46-2  
263880-47-3 263880-48-4 263880-49-5 263880-50-8 263880-52-0  
263880-53-1 263880-54-2 263880-55-3 263880-56-4 263880-57-5  
263880-58-6 263880-60-0 263880-61-1 263880-62-2 263880-63-3  
263880-65-5 263880-66-6 263880-67-7 263880-68-8 263880-70-2  
263880-71-3 263880-72-4 263880-73-5 263880-75-7 263880-76-8  
263880-77-9 263880-78-0 263880-80-4 263880-81-5 263880-82-6  
263880-83-7 263880-85-9 263880-87-1 263905-53-9 263905-54-0  
263905-55-1 263905-57-3

RL: CAT (Catalyst use); USES (Uses)

(weakly coordinating counterion component; transition metal

**complexes** having weakly coordinating counterions for catalysts  
for **polymerization** of cycloolefins)

IT 143-66-8, Sodium tetraphenylborate 1109-15-5,  
Tris(pentafluorophenyl)boron 2797-28-6, Lithium  
tetrakis(pentafluorophenyl)borate 14104-20-2, Silver tetrafluoroborate  
25776-12-9, Sodium tetrakis(4-fluorophenyl)borate 26603-18-9, Sodium  
tetrakis(3-fluorophenyl)borate 55471-58-4 68140-33-0, Lithium  
tetrakis(4-fluorophenyl)borate 70083-57-7 79060-88-1, Sodium  
tetrakis(3,5-bis(trifluoromethyl)phenyl)borate 89171-23-3, Potassium  
tetrakis(pentafluorophenyl)borate 105560-52-9, Potassium  
tetrakis[bis(3,5-trifluoromethyl)phenyl]borate 118612-00-3,  
N,N-Dimethylanilinium tetrakis(pentafluorophenyl)borate 119861-51-7,  
Sodium tetrakis(3,5-difluorophenyl)borate 120945-63-3 121919-80-0  
136040-19-2, Trityl tetrakis(pentafluorophenyl)borate 142617-68-3  
143319-79-3 143607-32-3 144674-03-3 148354-26-1 148354-27-2,  
Triethylsilylium tetrakis(pentafluorophenyl)borate 149213-65-0, Sodium  
tetrakis(pentafluorophenyl)borate 153347-65-0, Lithium  
tetrakis(3,5-bis(trifluoromethyl)phenyl)borate 156713-63-2 157475-37-1  
160298-75-9, Silver tetrakis(4-fluorophenyl)borate 160298-76-0  
167172-26-1 167172-28-3 172883-38-4 177716-84-6 177716-86-8  
177716-87-9 177716-91-5 177716-92-6 177716-94-8 177716-99-3  
177717-01-0 177717-03-2 177717-05-4 177717-08-7 177717-10-1  
177717-12-3 188019-19-4, Thallium tetrakis[3,5-  
bis(trifluoromethyl)phenyl]borate 188707-89-3 191101-32-3  
220836-20-4 220836-25-9 225797-12-6 263878-81-5 263878-82-6  
263879-13-6, Lithium tetrakis(2-fluorophenyl)borate 263879-14-7, Sodium  
tetrakis(2-fluorophenyl)borate 263879-15-8, Silver tetrakis(2-  
fluorophenyl)borate 263879-16-9, Thallium tetrakis(2-fluorophenyl)borate  
263879-17-0, Lithium tetrakis(3-fluorophenyl)borate 263879-18-1, Silver  
tetrakis(3-fluorophenyl)borate 263879-19-2, Thallium  
tetrakis(3-fluorophenyl)borate 263879-21-6, Ferrocenium  
tetrakis(3-fluorophenyl)borate 263879-24-9, Thallium  
tetrakis(4-fluorophenyl)borate 263879-27-2, Lithium tetrakis(3,5-  
difluorophenyl)borate 263879-31-8 263879-32-9 263879-33-0  
263879-34-1 263879-35-2 263879-36-3 263879-37-4 263879-39-6  
263879-40-9 263879-41-0 263879-45-4 263879-46-5 263879-47-6  
263879-48-7 263879-49-8 263879-50-1 263879-51-2 263879-52-3  
263879-53-4 263879-54-5 263879-55-6 263879-56-7 263879-57-8  
263879-58-9 263879-59-0 263879-60-3 263879-61-4 263879-62-5  
263879-63-6 263879-64-7 263879-65-8 263879-66-9 263879-67-0  
263879-68-1 263879-69-2 263879-70-5 263879-71-6 263879-72-7  
263879-73-8 263879-74-9 263879-75-0 263879-76-1 263879-78-3  
263879-79-4 263879-80-7 263879-81-8 263879-82-9 263879-84-1  
263879-85-2 263879-86-3 263879-87-4 263879-88-5 263879-89-6  
263879-90-9 263879-91-0 263879-92-1 263879-93-2 263879-94-3  
263879-95-4 263879-96-5 263879-97-6 263879-98-7 263879-99-8  
263880-00-8

RL: CAT (Catalyst use); USES (Uses)

(weakly coordinating counterion component; transition **metal**  
**complexes** stabilized by weakly coordinating counterions for  
catalysts for **polymerization** of cycloolefins)

L85 ANSWER 7 OF 29 CAPLUS COPYRIGHT 2004 ACS on STN  
AN 2003:376424 CAPLUS  
DN 138:369398

ED Entered STN: 16 May 2003  
 TI Process for preparing aromatic **polymers**  
 IN Uckert, Frank P.  
 PA USA  
 SO U.S. Pat. Appl. Publ., 23 pp.  
 CODEN: USXXCO  
 DT Patent  
 LA English  
 IC ICM C08F004-44  
 NCL 526124600; 526124900; 526131000  
 CC 35-5 (Chemistry of Synthetic High Polymers)  
 Section cross-reference(s): 76

FAN.CNT 1

	PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
PI	US 2003092857	A1	20030515	US 2002-289946	20021107
	WO 2003042276	A2	20030522	WO 2002-US35782	20021107
	WO 2003042276	A3	20040304		
	W:	AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BY, BZ, CA, CH, CN, CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, ES, FI, GB, GD, GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KP, KR, KZ, LC, LK, LR, LS, LT, LU, LV, MA, MD, MG, MK, MN, MW, MX, MZ, NO, NZ, OM, PH, PL, PT, RO, RU, SC, SD, SE, SG, SI, SK, SL, TJ, TM, TN, TR, TT, TZ, UA, UG, US, UZ, VC, VN, YU, ZA, ZM, ZW, AM, AZ, BY, KG, KZ, MD, RU, TJ, TM			
	RW:	GH, GM, KE, LS, MW, MZ, SD, SL, SZ, TZ, UG, ZM, ZW, AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, IE, IT, LU, MC, NL, PT, SE, SK, TR, BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG			

PRAI US 2001-348830P P 20011113  
 US 2002-365389P P 20020318

AB Conjugated aromatic **polymers**, useful for manufacture of **electronic devices**, are prepared by **polymerization** of a mixture containing XAr<sub>1</sub>X (X = Br, I, Cl, p-toluenesulfonate, methanesulfonate, or trifluoromethanesulfonate, Ar<sub>1</sub> = aromatic group) and YAr<sub>2</sub>Y (Y = boronic acid, boronic ester, or borane, Ar<sub>2</sub> = aromatic group the same or different than Ar<sub>2</sub>) or a mixture of aromatic monomers having both of the above-described groups in the presence of catalysts based on a phosphine oxide-transition **metal complex** having 2 **metal** atoms bonded to ≥1 phosphine oxide ligand, wherein each metal is bonded to the ligands via metal-P bonds and wherein the metal atoms are bridged via 2 halogen atoms. A typical **polymer** was manufactured by **polymn** . of 1.07 g 2,7-diiodo-9,9-bis(2-ethylhexyl)fluorene 48 h at 100° with 0.5 g 1,4-benzenediboronic acid bis(neopentyl glycol) cyclic ester in DMF in the presence K<sub>2</sub>CO<sub>3</sub> and [bis(di-tert-butylphosphinous acid)]palladium (I) chloride dimer.

ST conjugated arom **polymer** manuf phosphorus transition **metal complex** catalyst; tertiary butylphosphinous acid palladium chloride dimer catalyst **polymn**; diiodobisethylhexylfluorene benzenediboronic acid bisneopentyl glycol cyclic ester copolymer manuf

IT **Polymers**, preparation

RL: IMF (Industrial manufacture); PREP (Preparation)

(conjugated, aromatic; preparing conjugated aromatic **polymers** in presence of phosphine oxide-transition **metal**

complexes)

IT Electroluminescent devices  
Polymerization catalysts  
(preparing conjugated aromatic polymers in presence of phosphine  
oxide-transition metal complexes)

IT 13716-10-4, Di-tert-butylchlorophosphine  
RL: RCT (Reactant); RACT (Reactant or reagent)  
(catalyst precursor; preparing conjugated aromatic polymers in  
presence of phosphine oxide-transition metal  
complexes)

IT 386706-31-6P 386706-32-7P  
RL: CAT (Catalyst use); IMF (Industrial manufacture); PREP  
(Preparation); USES (Uses)  
(preparing conjugated aromatic polymers in presence of phosphine  
oxide-transition metal complexes)

IT 475114-78-4P  
RL: IMF (Industrial manufacture); PREP (Preparation)  
(preparing conjugated aromatic polymers in presence of phosphine  
oxide-transition metal complexes)

L85 ANSWER 8 OF 29 WPIX COPYRIGHT 2004 THOMSON DERWENT on STN  
AN 2004-011765 [01] WPIX  
DNN N2004-008624 DNC C2004-003436  
TI Luminescence-capable material as component in optical device,  
e.g. electroluminescent device, comprises conjugated  
polymer or oligomer and organometallic group covalently bound to  
polymer or oligomer.

DC A26 A85 L03 U11  
IN EVANS, N; HOLMES, A; KOEHLER, A; SANDEE, A; WILLIAMS, C  
PA (UYCA-N) UNIV CAMBRIDGE TECH SERVICES LTD  
CYC 102  
PI WO 2003091355 A2 20031106 (200401)\* EN 79p C09K000-00  
RW: AT BE BG CH CY CZ DE DK EA EE ES FI FR GB GH GM GR HU IE IT KE LS  
LU MC MW MZ NL OA PT RO SD SE SI SK SL SZ TR TZ UG ZM ZW  
W: AE AG AL AM AT AU AZ BA BB BG BR BY BZ CA CH CN CO CR CU CZ DE DK  
DM DZ EC EE ES FI GB GD GE GH GM HR HU ID IL IN IS JP KE KG KP KR  
KZ LC LK LR LS LT LU LV MA MD MG MK MN MW MX MZ NO NZ OM PH PL PT  
RO RU SC SD SE SG SK SL TJ TM TN TR TT TZ UA UG US UZ VC VN YU ZA  
ZM ZW

ADT WO 2003091355 A2 WO 2003-GB1765 20030424  
PRAI GB 2002-9652 20020426  
IC ICM C09K000-00  
AB WO2003091355 A UPAB: 20040102  
NOVELTY - A luminescence-capable material comprises a  
polymer or oligomer; and an organometallic group. The  
polymer or oligomer is at least partially conjugated and the  
organometallic group is covalently bound to the polymer or  
oligomer. The nature, location and/or proportion of the polymer  
or oligomer and of the organometallic group in the material are selected  
so that the luminescence predominantly is  
phosphorescence.

DETAILED DESCRIPTION - INDEPENDENT CLAIMS are also included for:  
(a) an optical device or a component comprising a substrate and a  
luminescence-capable material supported on the substrate;  
(b) a monomer for use in a polymerization reaction having

the formula X-M((spacer)p-organometallic)-X' or X-organometallic-X';

(c) an end-capping reagent for use in a **polymerization** reaction having a formula X-M((spacer)p-organometallic) or X-organometallic;

(d) a process for preparing a **luminescence**-capable material by reacting monomers to form a **polymer** or oligomer; terminating the **polymer** or oligomer using an end-capping reagent; and treating the terminated **polymer** or oligomer with a **metal-complexing** reagent, when the end-capping reagent is capable of forming a **metal complex**.

X, X' = reactive halide, boronic acid, boronic ester, or borane;

p = at least 0;

M = aryl or heteroaryl;

L = ligand capable of forming a **complex** with a **metal** when treated with a **metal-complexing** reagent.

The organometallic in the formula X-organometallic-X' includes a carbon-metal bond. Preferably, the organometallic does not comprise ruthenium.

USE - As a component in an optical device, e.g. **electroluminescent** device (claimed).

ADVANTAGE - The invention provides a new material that is capable predominantly of **phosphorescence**, preferably electrophosphorescence. This material is superior to a **polymer** blend incorporating a **phosphorescent** dopant. The controlled structure of the material of the invention means that the location and mobility of the organometallic in the material is spatially controlled. This spatial control enables control of the interaction between the **polymer** or oligomer and the organometallic. This, in turn, enables manipulation, particularly to some extent of the energy levels of the material in its excited state when the organometallic is conjugatively linked to the **polymer** or oligomer because of synergistic effects between the **polymer** or oligomer and the organometallic. The **luminescence**-capable material of the invention gives bright **phosphorescence** in solution-processed devices. It is homogeneous and solution-processable.

Dwg.0/15

FS CPI EPI

FA AB

MC CPI: A09-A03A; A12-E11C; L03-G05F

EPI: U11-A15

L85 ANSWER 9 OF 29 WPIX COPYRIGHT 2004 THOMSON DERWENT on STN

AN 2004-107351 [11] WPIX

DNN N2004-085310 DNC C2004-043845

TI Organic **electroluminescent** device has hole transport layer and light emitting layer containing host substance and **phosphorescent** dopant.

DC A18 A23 A85 E12 E13 L03 U11 U14 X26

IN CHIN, B D; KIM, M H; KWON, J H; LEE, S T; SUH, M C

PA (SMSU) SAMSUNG DENKAN KK; (SMSU) SAMSUNG SDI CO LTD

CYC 2

PI US 2003234607 A1 20031225 (200411)\* 8p H01L021-00

JP 2004022544 A 20040122 (200411) 11p H05B033-14

ADT US 2003234607 A1 US 2003-404134 20030402; JP 2004022544 A JP 2003-168292



20030612

PRAI KR 2002-34692 20020620

IC ICM H01L021-00; H05B033-14

ICS C09K011-06; H01J001-62; H01L033-00

AB US2003234607 A UPAB: 20040213

NOVELTY - An organic **electroluminescent** device has electrode (100), hole transport layer (300), light emitting layer (200) and another electrode (400). The light emitting layer contains host substance and **phosphorescent** dopant.

DETAILED DESCRIPTION - An INDEPENDENT CLAIM is included for light emitting film mixture.

USE - Used as organic **electroluminescent** device.

ADVANTAGE - The organic **electroluminescent** device has improved color purity, light emitting characteristics and laser induced thermal imaging characteristics.

DESCRIPTION OF DRAWING(S) - The figure shows the cross-sectional view of an organic **electroluminescent** device.

electrodes 100,400

light emitting layer 200

hole transporting layer 300

Dwg.2/2

FS CPI EPI

FA AB; GI; DCN

MC CPI: A12-E11C; E05-N; E05-P; E06-D13; E07-D02; E07-E04; E08-B; E10-A19B; E10-B04A2; E10-J02B4; L03-G05F

EPI: U11-A15B; U14-J; X26-J

L85 ANSWER 10 OF 29 WPIX COPYRIGHT 2004 THOMSON DERWENT on STN

AN 2004-167025 [16] WPIX

CR 2004-097210 [10]; 2004-106835 [11]; 2004-141650 [14]

DNN N2004-133119 DNC C2004-066197

TI Cleaning tableware for cleaning, sanitizing, and stain removal tableware, involves contacting tableware with aqueous cleaning liquor and bleaching liquor.

DC A97 D25 E19 P28 P43 S03

IN DRZEWIECKI, P J; PRICE, K N; SCHEPER, W M; TREMBLAY, M E; BALLAS, J E; CHIAO, I J; SHOWELL, M S; WAUGH, K L

PA (PROC) PROCTER & GAMBLE CO

CYC 102

PI US 2003213503 A1 20031120 (200416)\* 34p B08B007-04

WO 2003097782 A1 20031127 (200416) EN C11D003-395

RW: AT BE BG CH CY CZ DE DK EA EE ES FI FR GB GH GM GR HU IE IT KE LS LU MC MW MZ NL OA PT RO SD SE SI SK SL SZ TR TZ UG ZM ZW

W: AE AG AL AM AT AU AZ BA BB BG BR BY BZ CA CH CN CO CR CU CZ DE DK DM DZ EC EE ES FI GB GD GE GH GM HR HU ID IL IN IS JP KE KG KP KR KZ LC LK LR LS LT LU LV MA MD MG MK MN MW MX MZ NI NO NZ OM PH PL PT RO RU SC SD SE SG SK SL TJ TM TN TR TT TZ UA UG UZ VN YU ZA ZW

WO 2003099096 A1 20031204 (200416) EN A47L015-00

RW: AT BE BG CH CY CZ DE DK EA EE ES FI FR GB GH GM GR IE IT KE LS LU MC MW MZ NL OA PT SD SE SK SL SZ TR TZ UG ZM ZW

W: AE AG AL AM AT AU AZ BA BB BG BR BY BZ CA CH CN CO CR CU CZ DE DK DM DZ EC EE ES FI GB GD GE GH GM HR HU ID IL IN IS JP KE KG KP KR KZ LC LK LR LS LT LU LV MA MD MG MK MN MW MX MZ NO NZ OM PH PL PT RO RU SD SE SG SI SK SL TJ TM TN TR TT TZ UA UG UZ VN YU ZA ZW

WO 2003099097 A1 20031204 (200416) EN A47L015-00

RW: AT BE BG CH CY CZ DE DK EA EE ES FI FR GB GH GM GR IE IT KE LS LU  
MC MW MZ NL OA PT SD SE SK SL SZ TR TZ UG ZM ZW  
W: AE AG AL AM AT AU AZ BA BB BG BR BY BZ CA CH CN CO CR CU CZ DE DK  
DM DZ EC EE ES FI GB GD GE GH GM HR HU ID IL IN IS JP KE KG KP KR  
KZ LC LK LR LS LT LU LV MA MD MG MK MN MW MX MZ NO NZ OM PH PL PT  
RO RU SD SE SG SI SK SL TJ TM TN TR TT TZ UA UG UZ VN YU ZA ZW

WO 2003099982 A1 20031204 (200416) EN C11D003-395

RW: AT BE BG CH CY CZ DE DK EA EE ES FI FR GB GH GM GR IE IT KE LS LU  
MC MW MZ NL OA PT SD SE SK SL SZ TR TZ UG ZM ZW  
W: AE AG AL AM AT AU AZ BA BB BG BR BY BZ CA CH CN CO CR CU CZ DE DK  
DM DZ EC EE ES FI GB GD GE GH GM HR HU ID IL IN IS JP KE KG KP KR  
KZ LC LK LR LS LT LU LV MA MD MG MK MN MW MX MZ NO NZ OM PH PL PT  
RO RU SD SE SG SI SK SL TJ TM TN TR TT TZ UA UG UZ VN YU ZA ZW

WO 2003099983 A1 20031204 (200416) EN C11D003-395

RW: AT BE BG CH CY CZ DE DK EA EE ES FI FR GB GH GM GR IE IT KE LS LU  
MC MW MZ NL OA PT SD SE SK SL SZ TR TZ UG ZM ZW  
W: AE AG AL AM AT AU AZ BA BB BG BR BY BZ CA CH CN CO CR CU CZ DE DK  
DM DZ EC EE ES FI GB GD GE GH GM HR HU ID IL IN IS JP KE KG KP KR  
KZ LC LK LR LS LT LU LV MA MD MG MK MN MW MX MZ NO NZ OM PH PL PT  
RO RU SD SE SG SI SK SL TJ TM TN TR TT TZ UA UG UZ VN YU ZA ZW

ADT US 2003213503 A1 Provisional US 2002-381146P 20020517, Provisional US  
2002-381455P 20020517, Provisional US 2002-381472P 20020517, Provisional  
US 2002-381473P 20020517, US 2002-222643 20020816; WO 2003097782 A1 WO  
2003-US15233 20030515; WO 2003099096 A1 WO 2002-US26038 20020816; WO  
2003099097 A1 WO 2002-US26137 20020816; WO 2003099982 A1 WO 2002-US26182  
20020816; WO 2003099983 A1 WO 2002-US26183 20020816

PRAI US 2002-222643 20020816; US 2002-381146P 20020517; US 2002-381455P  
20020517; US 2002-381472P 20020517; US 2002-381473P 20020517

IC ICM A47L015-00; B08B007-04; C11D003-395

ICS A47L015-42; A47L015-44; C11D003-02; C11D003-386

AB US2003213503 A UPAB: 20040305

NOVELTY - Cleaning tableware comprises contacting tableware with aqueous  
cleaning liquor containing bleach unstable ingredient and aqueous  
bleaching liquor containing electrolysis products of electrolytes. The  
electrolytes are halide anions and/or halite anions.

DETAILED DESCRIPTION - An INDEPENDENT CLAIM is included for an  
article comprising a package and a replacement signal-providing detergent  
composition.

USE - For cleaning, sanitizing, and stain removal tableware.

ADVANTAGE - The invention eliminates the need for liquid chlorine  
bleach to be supplied into the final step of automatic dish washing  
process.

DESCRIPTION OF DRAWING(S) - The figure shows an automatic dish  
washing appliance with two electrochemical cells.

dish washing appliance 200

Tap water 201

Water feed pipes 202, 203, 243

Water valve 204

Electrochemical cell 205

Outlet port 207, 237

Dwg.1/4

FS CPI EPI GMPI

FA AB; GI; DCN

MC CPI: A12-W12B; D11-A; D11-B02; D11-B03; D11-B11; D11-D01A; E05-G03C;  
E05-G09D; E07-A02B; E10-B01C1; E10-B02; E10-C02A; E10-C04D4; E31-A05;

E31-B03; E31-C; E31-F04; E31-H05; E31-K06; E31-N05B; E31-N05C;  
E31-P02D; E35

EPI: S03-E14B

L85 ANSWER 11 OF 29 CAPLUS COPYRIGHT 2004 ACS on STN DUPLICATE 3  
AN 2002:294029 CAPLUS  
DN 136:316681  
ED Entered STN: 19 Apr 2002  
TI **Polymers** having attached **luminescent metal complexes** and devices made with such **polymers**  
IN Periyasamy, Mookkan; Grushin, Vladimir; Petrov, Viacheslav A.; Herron, Norman; Radu, Nora Sabina  
PA E. I. Du Pont de Nemours & Co., USA  
SO PCT Int. Appl., 58 pp.  
CODEN: PIXXD2  
DT Patent  
LA English  
IC ICM H01L051-30  
CC 73-5 (Optical, Electron, and Mass Spectroscopy and Other Related Properties)  
Section cross-reference(s): 38, 76  
FAN.CNT 1

	PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
PI	WO 2002031896	A2	20020418	WO 2001-US31449	20011009
	WO 2002031896	A3	20030904		
	W:	AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BY, BZ, CA, CH, CN, CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, ES, FI, GB, GD, GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KP, KR, KZ, LC, LK, LR, LS, LT, LU, LV, MA, MD, MG, MK, MN, MW, MX, MZ, NO, NZ, PH, PL, PT, RO, RU, SD, SE, SG, SI, SK, SL, TJ, TM, TR, TT, TZ, UA, UG, UZ, VN, YU, ZA, ZW, AM, AZ, BY, KG, KZ, MD, RU, TJ, TM			
	RW:	GH, GM, KE, LS, MW, MZ, SD, SL, SZ, TZ, UG, ZW, AT, BE, CH, CY, DE, DK, ES, FI, FR, GB, GR, IE, IT, LU, MC, NL, PT, SE, TR, BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG			
	AU 2002015322	A5	20020422	AU 2002-15322	20011009
	EP 1364419	A2	20031126	EP 2001-983933	20011009
	R:	AT, BE, CH, DE, DK, ES, FR, GB, GR, IT, LI, LU, NL, SE, MC, PT, IE, SI, LT, LV, FI, RO, MK, CY, AL, TR			
PRAI	US 2000-238974P	P	20001010		
	WO 2001-US31449	W	20011009		
OS	MARPAT 136:316681				
AB	Organic <b>electronic devices</b> are described which comprise an emitting layer which comprises $\geq 1$ functionalized <b>polymer</b> having a plurality of first-type functional groups, at least a portion of the functional groups being coordinated to $\geq 1$ <b>metal</b> or <b>metal-containing complex</b> , or in which the groups have a charge and are associated with $\geq 1$ <b>metal complex</b> having an opposite charge. The emitting layers may also include organic charge transport materials. Selected <b>polymer-metal complexes</b> and salts are also described.				
ST	<b>metal complex polymer salt electroluminescent device; metal polymer complex electroluminescent device</b>				
IT	Group VIII element compounds				

RL: DEV (Device component use); USES (Uses)  
 (Group 10; **metal-polymer complexes** and salts and devices employing them)

IT Polyanilines  
 RL: DEV (Device component use); USES (Uses)  
 (charge transport material; **metal-polymer complexes** and salts and devices employing them)

IT Group VIII element compounds  
 RL: DEV (Device component use); USES (Uses)  
 (cobalt-group; **metal-polymer complexes** and salts and devices employing them)

IT **Luminescent** substances  
 (**electroluminescent**; **metal-polymer complexes** and salts and devices employing them)

IT Group VIII element compounds  
 RL: DEV (Device component use); USES (Uses)  
 (iron-group; **metal-polymer complexes** and salts and devices employing them)

IT **Electroluminescent** devices  
 (**metal-polymer complexes** and salts and devices employing them)

IT Group IB element compounds  
 Group IIB element compounds  
 Group IIIA element compounds  
 Group VIIB element compounds  
 Rare earth **complexes**  
 RL: DEV (Device component use); USES (Uses)  
 (**metal-polymer complexes** and salts and devices employing them)

IT 25067-59-8, Polyvinylcarbazole 58328-31-7 65181-78-4,  
 N,N'-Diphenyl-N,N'-bis(3-methylphenyl)-(1,1'-biphenyl)-4,4'-diamine  
 70895-80-6, Bis[4-(N,N-diethylamino)-2-methylphenyl](4-methylphenyl)methane  
 RL: DEV (Device component use); USES (Uses)  
 (charge transport material; **metal-polymer complexes** and salts and devices employing them)

IT 7439-88-5D, Iridium, compds., reaction products with **polymers**  
 7440-04-2D, Osmium, compds., reaction products with **polymers**  
 7440-05-3D, Palladium, compds., reaction products with **polymers**  
 7440-06-4D, Platinum, compds., reaction products with **polymers**  
 7440-16-6D, Rhodium, compds., reaction products with **polymers**  
 7440-18-8D, Ruthenium, compds., reaction products with **polymers**  
 7440-27-9D, Terbium, compds., reaction products with **polymers**  
 7440-30-4D, Thulium, compds., reaction products with **polymers**  
 7440-57-5D, Gold, compds., reaction products with **polymers**  
 7440-66-6D, Zinc, compds., reaction products with **polymers**  
 40231-87-6D, reaction products with **polymers** 176763-58-9D,  
 reaction products with **polymers** 412040-84-7D, reaction products with **polymers**  
 RL: DEV (Device component use); USES (Uses)  
 (**metal-polymer complexes** and salts and devices employing them)

IT 126213-51-2, Poly(3,4-ethylenedioxythiophene)  
 RL: DEV (Device component use); POF (Polymer in formulation); USES (Uses)  
 (**metal-polymer complexes** and salts and

devices employing them)

IT 14054-87-6DP, reaction products with **polymers** 14592-81-5DP, reaction products with **polymers** 26284-14-0DP, reaction products with **metal** compds. 26355-01-1DP, 2-Hydroxyethyl methacrylate-methyl methacrylate copolymer, reaction products with **metal** compds. 56315-94-7DP, 2-Hydroxyethyl methacrylate-isobutyl methacrylate copolymer, reaction products with **metal** compds. 66028-15-7DP, 2-(Dimethylamino)ethyl methacrylate-Isobutylmethacrylate copolymer, reaction products with **metal** compds. 72460-28-7DP, 4,4'-Bis(chlorocarbonyl)-2,2'-bipyridine, reaction products with **polymers** and **metal** compds. 190370-38-8DP, reaction products with **polymers** 387859-66-7DP, reaction products with **polymers** 412032-55-4DP, reaction products with electron-transporting compds. and **metal** compds. 412032-56-5DP, reaction products with **polymers** and **metal** compds. 412032-57-6DP, reaction products with electron-transporting compds. and **metal** compds. 412032-58-7DP, reaction products with **metal** compds. 412032-59-8DP, reaction products with **metal** compds. 412032-60-1DP, reaction products with **metal** compds.

RL: DEV (Device component use); SPN (Synthetic preparation); **PREP (Preparation)**; USES (Uses)

(**metal-polymer complexes** and salts and devices employing them)

IT 95-54-5, 1,2-Diaminobenzene, reactions 97-93-8, Triethylaluminum, reactions 694-83-7, 1,2-Diaminocyclohexane 1765-93-1, 4-Fluorophenylboronic acid 2695-37-6, 4-Styrenesulfonic acid sodium salt 3796-23-4 10025-83-9, Iridium trichloride 32503-27-8, Tetrabutylammonium hydrogen sulfate 37942-07-7, 3,5-Di-tert-butyl-2-hydroxybenzaldehyde

RL: RCT (Reactant); RACT (Reactant or reagent)

(**metal-polymer complexes** and salts and devices employing them)

IT 37295-36-6P 66028-15-7P, 2-(Dimethylamino)ethyl methacrylate-Isobutylmethacrylate copolymer 103595-82-0P 190370-38-8P 370878-58-3P 387859-66-7P

RL: RCT (Reactant); SPN (Synthetic preparation); **PREP (Preparation)**; RACT (Reactant or reagent)

(**metal-polymer complexes** and salts and devices employing them)

L85 ANSWER 12 OF 29 CAPLUS COPYRIGHT 2004 ACS on STN

AN 2002:978183 CAPLUS

DN 138:63589

ED Entered STN: 29 Dec 2002

TI Emissive multichromophoric systems

IN Therien, Michael J.

PA The Trustees of the University of Pennsylvania, USA

SO PCT Int. Appl., 76 pp.

CODEN: PIXXD2

DT Patent

LA English

IC ICM H05B

CC 73-5 (Optical, Electron, and Mass Spectroscopy and Other Related Properties)

Section cross-reference(s): 74, 76, 78

FAN.CNT 1

	PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
PI	WO 2002104072	A2	20021227	WO 2002-US5584	20020226
	WO 2002104072	A3	20030605		
	W:				
	AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BY, BZ, CA, CH, CN,				
	CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, ES, FI, GB, GD, GE, GH,				
	GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KP, KR, KZ, LC, LK, LR,				
	LS, LT, LU, LV, MA, MD, MG, MK, MN, MW, MX, MZ, NO, NZ, PH, PL,				
	PT, RO, RU, SD, SE, SG, SI, SK, SL, TJ, TM, TR, TT, TZ, UA, UG,				
	US, UZ, VN, YU, ZA, ZW, AM, AZ, BY, KG, KZ, MD, RU, TJ, TM				
	RW:				
	GH, GM, KE, LS, MW, MZ, SD, SL, SZ, TZ, UG, ZM, ZW, AT, BE, CH,				
	CY, DE, DK, ES, FI, FR, GB, GR, IE, IT, LU, MC, NL, PT, SE, TR,				
	BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG				
	EP 1363916	A2	20031126	EP 2002-763188	20020226
	R:				
	AT, BE, CH, DE, DK, ES, FR, GB, GR, IT, LI, LU, NL, SE, MC, PT,				
	IE, SI, LT, LV, FI, RO, MK, CY, AL, TR				
	US 2004067198	A1	20040408	US 2003-467107	20030805
PRAI	US 2001-271520P	P	20010226		
	US 2001-306504P	P	20010719		
	WO 2002-US5584	W	20020226		
AB	Methods of producing light in the 650-2000 nm region are described which entail exciting a conjugated compound comprising $\geq 2$ covalently bound moieties so that the light produced exceeds the total produced independently by the moieties. Preferably, the transition dipoles of the moieties are correlated in defined phase relationships. Lasers, optical amplifiers, light-sensitive elements, and <b>electroluminescent</b> devices employing the materials are also described. Polymer grid systems (e.g., electrodes, triodes) comprising a body of elec. conducting organic polymer having an open and porous network morphol. and an active <b>electronic</b> material located within at least a portion of the void spaces defined by the porous network are described in which the active <b>electronic</b> material comprises the conjugated compds.				
ST	laser emissive multichromophoric system; optical amplifier emissive multichromophoric system; emissive multichromophoric system; <b>electroluminescent</b> device emissive multichromophoric system; photodetector emissive multichromophoric system				
IT	<b>Luminescent</b> substances (emissive multichromophoric systems)				
IT	Conducting polymers (emissive multichromophoric systems and devices using them)				
IT	Dyes (laser; emissive multichromophoric systems)				
IT	Dye lasers <b>Electroluminescent</b> devices Optical amplifiers Optical detectors (using emissive multichromophoric systems)				
IT	156821-65-7P RL: DEV (Device component use); SPN (Synthetic preparation); PREP (Preparation); USES (Uses) (doped; emissive multichromophoric systems and devices using them)				
IT	162478-94-6P 479506-72-4P 479506-76-8P 479506-84-8P 479506-88-2P				

RL: DEV (Device component use); SPN (Synthetic preparation);

PREP (Preparation); USES (Uses)

(emissive multichromophoric systems and devices using them)

IT 76-05-1, Trifluoroacetic acid, reactions 98-59-9, p-Toluenesulfonyl chloride 100-52-7, Benzaldehyde, reactions 112-35-6, Triethylene glycol monomethyl ether 128-08-5, N-Bromosuccinimide 429-41-4, Tetrabutylammonium fluoride 557-34-6, Zinc acetate 624-95-3, 3,3-Dimethyl-1-butanol 1066-54-2, Trimethylsilylacetylene 2975-46-4, Trimethylsilylpropynal 3437-95-4, 2-Iodothiophene 4039-32-1, Lithium bistrimethylsilylamide 5158-46-3, Methyl zinc chloride 7486-35-3 7646-85-7, Zinc dichloride, reactions 7718-54-9, Nickel dichloride, reactions 15979-38-1 21211-65-4, 2,2'-Dipyrrylmethane 26153-38-8, 3,5-Dihydroxybenzaldehyde 39175-16-1, 2,5-Dimethoxyphenyl lithium 42930-39-2, Butyl zinc chloride 54329-76-9 68880-56-8 78389-87-4, Trimethylsilyl ethynyl zinc chloride 146985-15-1 146985-16-2 147470-64-2 156821-57-7 156821-62-4 156821-63-5 162456-73-7 162456-74-8 162479-04-1 162479-06-3 162479-07-4 162479-08-5 162479-10-9 162524-13-2 342888-11-3 479506-92-8

RL: RCT (Reactant); RACT (Reactant or reagent)

(emissive multichromophoric systems and devices using them)

IT 7440-66-6DP, Zinc, reaction products with porphyrins 22112-89-6P, 5,15-Diphenylporphyrin 62921-74-8P 147470-60-8P 151256-86-9P, 5,15-Dibromo-10,20-diphenylporphyrin 156821-62-4DP, (5-Bromo-10,20-diphenylporphinato)zinc, reaction products with zinc 162479-00-7P 162479-02-9P 206049-38-9P 320730-84-5P 446033-33-6P 446033-37-0P 446034-12-4P 446034-13-5P 446034-15-7P 446034-16-8P 448896-67-1P 448896-68-2P 448896-70-6P 448896-71-7P 448896-72-8P 448896-73-9P 448896-74-0P 448896-75-1P 479506-65-5P 479506-69-9P 479506-80-4P 479506-96-2P

RL: RCT (Reactant); SPN (Synthetic preparation); PREP

(Preparation); RACT (Reactant or reagent)

(emissive multichromophoric systems and devices using them)

IT 146985-18-4P 147470-61-9P 147470-62-0P 147470-63-1P 151462-68-9P 151462-70-3P 151462-71-4P 151530-24-4P 156821-55-5P 156821-56-6P 156821-59-9P 162479-11-0P 162524-03-0P 175597-07-6P 448896-69-3P 479506-57-5P

RL: SPN (Synthetic preparation); PREP (Preparation)

(emissive multichromophoric systems and devices using them)

IT 156821-60-2P 333363-22-7P 333391-12-1P 448896-65-9P 448896-66-0P 448946-00-7P 479506-61-1P

RL: SPN (Synthetic preparation); TEM (Technical or engineered material use); PREP (Preparation); USES (Uses)

(emissive multichromophoric systems and devices using them)

L85 ANSWER 13 OF 29 CAPLUS COPYRIGHT 2004 ACS on STN

AN 2002:727159 CAPLUS

DN 137:255143

ED Entered STN: 25 Sep 2002

TI Phenazasiline-containing  $\pi$ -conjugated polymers, their manufacture, and their application

IN Hayashi, Hideki; Nakao, Hidenobu; Okita, Koichi; Hayashi, Teruyuki; Tanaka, Masato

PA Ministry of Economy, Trade and Industry; National Industrial Research Institute, Japan

SO Jpn. Kokai Tokkyo Koho, 6 pp.

CODEN: JKXXAF

DT Patent

LA Japanese

IC ICM C08G061-12

ICS C09K009-02; C09K011-06; G02F001-15; H05B033-14; H05B033-22

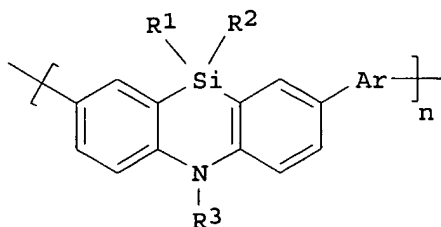
CC 73-12 (Optical, Electron, and Mass Spectroscopy and Other Related Properties)

Section cross-reference(s): 37, 74, 76

FAN.CNT 1

	PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
PI	JP 2002275249	A2	20020925	JP 2001-74813	20010315
PRAI	JP 2001-74813		20010315		

GI



I

AB The polymers are shown as I (R1, R2 = alkyl, aryl, alkoxy, aryloxy; R3 = H, alkyl, aryl, alkoxy, aryloxy; Ar = divalent aromatic; n = 3-30,000) and manufactured by reacting halogenated phenazasilines with distannyl compds. or diboryl compds. in the presence of P catalysts. **Electronic** or light-emitting devices using organic films containing the polymers and organic thin-film electrochromic or **electroluminescent** devices using the polymers are also claimed. The polymers have high heat resistance and strength, good elec. and optical properties, etc., are easily dissolved in organic solvents to give films.

ST phenazasiline polymer manuf electrochromic **electroluminescent** device

IT Electrochromic devices

**Electroluminescent** devices

(phenazasiline-containing  $\pi$ -conjugated polymers and their manufacture for electrochromic and **electroluminescent** devices)

IT 461053-41-8P 461053-42-9P 461053-43-0P 461053-44-1P

RL: DEV (Device component use); IMF (Industrial manufacture); TEM (Technical or engineered material use);

PREP (Preparation); USES (Uses)

(phenazasiline-containing  $\pi$ -conjugated polymers and their manufacture for electrochromic and **electroluminescent** devices)

L85 ANSWER 14 OF 29 WPIX COPYRIGHT 2004 THOMSON DERWENT on STN

AN 2003-093180 [08] WPIX

DNN N2003-073840 DNC C2003-023425

TI **Electroluminescent** device, used in liquid crystal displays, includes an **electroluminescent** layer comprising a complex of a rare earth, transition, lanthanide or actinide metal and a non rare earth metal.



DC A85 E19 E23 L03 U14  
IN KATHIRGAMANATHAN, P; RAVICHANDRAN, S; SURENDRAKUMAR, S  
PA (ELAM-N) ELAM-T LTD  
CYC 100  
PI WO 2002087283 A1 20021031 (200308)\* EN 58p H05B033-14  
RW: AT BE CH CY DE DK EA ES FI FR GB GH GM GR IE IT KE LS LU MC MW MZ  
NL OA PT SD SE SL SZ TR TZ UG ZM ZW  
W: AE AG AL AM AT AU AZ BA BB BG BR BY BZ CA CH CN CO CR CU CZ DE DK  
DM DZ EC EE ES FI GB GD GE GH GM HR HU ID IL IN IS JP KE KG KP KR  
KZ LC LK LR LS LT LU LV MA MD MG MK MN MW MX MZ NO NZ OM PH PL PT  
RO RU SD SE SG SI SK SL TJ TM TN TR TT TZ UA UG US UZ VN YU ZA ZM  
ZW  
ADT WO 2002087283 A1 WO 2002-GB1844 20020422  
PRAI GB 2001-9755 20010420  
IC ICM H05B033-14  
ICS C09K011-06  
AB WO 200287283 A UPAB: 20030204  
NOVELTY - **Electroluminescent** device comprises first and second  
electrodes and a layer of an **electroluminescent** material  
comprising an organic complex (I) or (II) of rare earth, transition,  
lanthanide or actinide metal and a non rare-earth metal.  
DETAILED DESCRIPTION - **Electroluminescent** device comprises  
first and second electrodes and a layer of an **electroluminescent**  
material comprising a complex of formula (I) or (II).  
(L alpha )nM1M2 (I)  
(L alpha )nM1M2(Lp) (II)  
M1 = rare earth, transition metal, lanthanide or actinide;  
M2 = non rare earth metal;  
L alpha = organic complex;  
n = combined valence state of M1 and M2; and  
Lp = neutral ligand.  
USE - The **electroluminescent** material is used in display  
applications such as liquid crystal devices and devices based on inorganic  
semiconductor systems.  
ADVANTAGE - The hole transporting layer serves to transport holes and  
to block the electrons, thus preventing electrons from moving into the  
electrode without recombining with holes. The recombination of carrier  
therefore mainly takes place in the emitter layer.  
Dwg.0/30  
FS CPI EPI  
FA AB; DCN  
MC CPI: A12-E07C; A12-L03B; E05-A; E05-B; E05-C02; E05-F02; E05-G02; E05-J;  
E05-K; E05-L; E05-M; E05-N; E05-P; E05-Q; E05-T; E24-A05; L03-G05F  
EPI: U14-J; U14-K01A  
L85 ANSWER 15 OF 29 WPIX COPYRIGHT 2004 THOMSON DERWENT on STN  
AN 2003-183825 [18] WPIX  
DNN N2003-144814 DNC C2003-048314  
TI New conjugated **polymers** especially useful as  
**electroluminescent** materials in **polymeric** light-emitting  
diodes comprise spirobifluorene-type units and fluorene-type units,.  
DC A26 L03 U11 U12 U14 X26  
IN BECKER, H; BUESING, A; FALCOU, A; PARHAM, A; SPREITZER, H; STOESSEL, P;  
TREACHER, K  
PA (COVI-N) COVION ORGANIC SEMICONDUCTORS GMBH

CYC 26

PI WO 2002077060 A1 20021003 (200318)\* DE 61p C08G061-00  
 RW: AT BE CH CY DE DK ES FI FR GB GR IE IT LU MC NL PT SE TR  
 W: AG CN DZ JP KR US

EP 1381639 A1 20040121 (200410) DE C08G061-00  
 R: AT BE CH CY DE DK ES FI FR GB GR IE IT LI LU MC NL PT SE TR  
 KR 2003092020 A 20031203 (200424) C08G061-12

ADT WO 2002077060 A1 WO 2002-EP3221 20020322; EP 1381639 A1 EP 2002-753715  
 20020322, WO 2002-EP3221 20020322; KR 2003092020 A KR 2003-712452 20030924

FDT EP 1381639 A1 Based on WO 2002077060

PRAI DE 2001-10114477 20010324

IC ICM C08G061-00; C08G061-12  
 ICS C09K011-06; H01L051-30; H05B033-14

AB WO 200277060 A UPAB: 20030317

NOVELTY - Conjugated **polymers** comprising spirobifluorene-type units (I) and fluorene-type units (II) are new.

DETAILED DESCRIPTION - Conjugated **polymers** comprising spirobifluorene-type units of formula (I) and fluorene-type units of formula (II) in a total amount of at least 20%, with a (I):(II) ratio is 1:10 to 10:1, are new:

X = CH, CR1 or N;

Z = a bond, CR3R4, CR3R4-CR3R4, CR3=CR4, O, S, NR5, CO, C=CR3R4 or SiR3R4;

R1 = 1-22C linear, branched or cyclic alkyl or alkoxy in which one or more nonadjacent C atoms can be replaced with NR5, O, S, COO or OCOO and one or more H atoms can be replaced with F; 5-40C aryl or aryloxy in which one or more C atoms can be replaced with O, S or N and which is optionally substituted by nonaromatic R1 groups, two or more of which can form a ring; or Cl, F, CN or N(R5)2;

R2 = 1-22C linear, branched or cyclic alkyl or alkoxy in which one or more nonadjacent C atoms can be replaced with NR5, O, S, COO or OCOO and one or more H atoms can be replaced with F; 5-40C aryl or aryloxy in which one or more C atoms can be replaced with O, S or N and which is optionally substituted by nonaromatic R1 groups; or CN;

R3, R4 = H; 1-22C linear, branched or cyclic alkyl or alkoxy in which one or more nonadjacent C atoms can be replaced with NR5, O, S, COO or OCOO and one or more H atoms can be replaced with F; 5-40C aryl or aryloxy in which one or more C atoms can be replaced with O, S or N and which is optionally substituted by nonaromatic R1 groups; or CN; or R3+R4 can form a ring; R5 = H; 1-22C linear, branched or cyclic alkyl or alkoxy in which one or more nonadjacent C atoms can be replaced with O, S, COO or OCOO and one or more H atoms can be replaced with F; or 5-40C aryl or aryloxy in which one or more C atoms can be replaced with O, S or N and which is optionally substituted by nonaromatic R1 groups;

n = 0-4;

m, o = 0-3;

provided that at least of n and/or m in at least one unit of formula (I) is nonzero.

USE - (I) are useful as **electroluminescent** materials in **polymeric** light-emitting diodes (PLEDs) and other **electronic devices**, especially organic integrated circuits, organic field effect transistors, organic thin film transistors, organic solar cells and organic laser diodes (all claimed).

Dwg.0/0

FS CPI EPI

FA AB; GI  
MC CPI: A09-A03A; A12-E11C; L04-E01A; L04-E03A  
EPI: U11-A15B; U12-A01A1X; U14-J02D2; X26-J

L85 ANSWER 16 OF 29 WPIX COPYRIGHT 2004 THOMSON DERWENT on STN  
AN 2004-064594 [07] WPIX  
DNN N2004-052290 DNC C2004-026574  
TI Semiconductor light emitting equipment has light-transmitting metalloxane gel layer covering semiconductor light emitting device anchored to the end of the one wiring conductor.  
DC A85 E12 L03 U12  
PA (SANK-N) SANKEN DENKI KK  
CYC 1  
PI JP 2002134790 A 20020510 (200407)\* 10p H01L033-00  
ADT JP 2002134790 A JP 2000-323179 20001023  
PRAI JP 2000-323179 20001023  
IC ICM H01L033-00  
ICS C09K011-80  
AB JP2002134790 A UPAB: 20040128

NOVELTY - Semiconductor light emitting equipment has a pair of wiring conductors, a semiconductor light emitting device anchored to the end of the one wiring conductor, and a light-transmitting metalloxane gel layer for covering the semiconductor light emitting device.

DETAILED DESCRIPTION - Semiconductor light emitting equipment has a pair of wiring conductors, a semiconductor light emitting device anchored to the end of the one wiring conductor, and a light-transmitting metalloxane gel layer for covering the semiconductor light emitting device. The metalloxane gel layer contains a **fluorescent** material having light transmission to blue light irradiated from the semiconductor light emitting device and absorbing the blue light irradiated from the light emitting device to convert the blue light into yellow light. The metalloxane gel layer is formed of a metalloxane sol obtained by applying hydrolytic **polymerization** to a metal alkoxide, or a metalloxane sol obtained by applying hydrolytic **polymerization** to an inorganic/organic **complex** consisting of a **metal** alkoxide and an organic resin, or a metalloxane sol consisting of a ceramic precursor **polymer**. The metalloxane gel layer firmly sticks the semiconductor light emitting device to the wiring conductors. The **fluorescent** material consists of  $(Y_{1-x}, Gdx)_3(Al_{1-y}, Gay)_{50}12:CezPrw$ .

$x = 0-0.5$ ;  
 $y = 0-0.5$ ;  
 $z = 0.001-0.5$ ;  
 $w = 0.001-0.5$ .

An INDEPENDENT CLAIM is included for the production of the semiconductor light emitting equipment, comprising:

- (a) forming a cup portion on the end of one wiring conductor of a pair of wiring conductors;
- (b) fixing the semiconductor light emitting device to the bottom of the cup portion;
- (c) electrically connecting electrodes formed on the upper surface of the semiconductor light emitting device to the pair of wiring conductors by means of bonding wires;
- (d) filling the **fluorescent** material and the metalloxane sol in the cup portion;

(e) covering the semiconductor light emitting device, the electrodes, and the ends of the bonding wires connected to the electrodes;

(f) drying/heating curing the metalloxane sol to form the metalloxane gel layer; and

(g) encapsulating the metalloxane gel layer by means of an encapsulating resin

The metalloxane gel layer is firmly stuck to the semiconductor light emitting device and the wiring conductors.

USE - The semiconductor light emitting equipment applies wavelength conversion to the light irradiated from the semiconductor light emitting device to outwardly release the light.

ADVANTAGE - The semiconductor light emitting device and the **fluorescent** material are surrounded by the metalloxane gel layer having stability under short wavelength light irradiation. The semiconductor light emitting equipment has enhanced resistance to environment. The semiconductor light emitting equipment has color rendering properties by using a host as garnet structure yttrium aluminum garnet and by using the Ce as an activator and the Pr as a co-activator.

DESCRIPTION OF DRAWING(S) - The drawing shows the semiconductor light-emitting-device (20).

Semiconductor light-emitting-element 2

Electrode (2a) of the cathode side of semiconductor light-emitting-element 2a

Wiring-conductor 3

Cup part 3a

Bottom-part of cup part 3b

Bonding wire 5

Dwg.1/9

FS CPI EPI

FA AB; GI; DCN

MC CPI: A06-D; A09-A02; A11-B05; A11-C02; A12-E04; A12-E07C; A12-E11A; E34-E; L04-E03

EPI: U12-A01

L85 ANSWER 17 OF 29 CAPLUS COPYRIGHT 2004 ACS on STN

AN 2002:412807 CAPLUS

DN 137:116037

ED Entered STN: 03 Jun 2002

TI Novel Preparation and Photoelectrochemical Properties of a Tungsten Oxide/Tris(2,2'-bipyridine)ruthenium(II) Complex Composite Film

AU Yagi, Masayuki; Umemiya, Saori

CS Faculty of Education and Human Sciences, Niigata University, Niigata, 950-2181, Japan

SO Journal of Physical Chemistry B (2002), 106(25), 6355-6357  
CODEN: JPCBFK; ISSN: 1089-5647

PB American Chemical Society

DT Journal

LA English

CC 72-2 (Electrochemistry)

Section cross-reference(s): 66, 73, 74, 76

AB A 1st and unique preparation is reported of a WO<sub>3</sub>/tris(2,2'-bipyridine)ruthenium(II) (Ru(bpy)<sub>3</sub><sup>2+</sup>) composite film by electrodeposition from a colloidal solution containing peroxotungstic acid and Ru(bpy)<sub>3</sub><sup>2+</sup> that is remarkably stabilized by poly(sodium 4-styrenesulfonate). The composite film clearly demonstrated multiple electrochromism. The photoexcited

Ru(bpy)<sub>3</sub><sup>2+</sup> is quenched completely by WO<sub>3</sub> in the composite film, which is responsible for an **electronic** interaction of Ru(bpy)<sub>3</sub><sup>2+</sup> with WO<sub>3</sub>. The complete quenching led to a photocharging-discharging character and a steady-state photoanodic current induced by visible light.

- ST prepn photoelectrochem property tungsten oxide ruthenium bipyridine composite film; electrodeposition tungsten oxide ruthenium bipyridine composite film; peroxotungstic acid electrodeposition tungsten oxide ruthenium bipyridine composite film; electrochromism tungsten oxide ruthenium bipyridine composite film
- IT Electrodeposits  
(composite; photoelectrochem. properties of WO<sub>3</sub>/Ru-bipyridine complex composite film with poly(Na styrenesulfonate))
- IT Electrodeposition  
(of WO<sub>3</sub>/Ru-bipyridine complex composite film from colloidal solution containing peroxotungstic acid and Ru-bipyridine complex and poly(Na styrenesulfonate))
- IT **Luminescence**  
Thickness  
UV and visible spectra  
(of WO<sub>3</sub>/Ru-bipyridine complex composite film with poly(Na styrenesulfonate))
- IT Cyclic voltammetry  
(of WO<sub>3</sub>/Ru-bipyridine complex composite film with poly(Na styrenesulfonate) in KNO<sub>3</sub> solution)
- IT Photocurrent  
(of WO<sub>3</sub>/Ru-bipyridine complex composite film with poly(Na styrenesulfonate) on ITO electrode in KNO<sub>3</sub> solution with and without cresol)
- IT 7757-79-1, Nitric acid potassium salt, uses  
RL: NUU (Other use, unclassified); PRP (Properties); USES (Uses)  
(cyclic voltammetry of WO<sub>3</sub>/Ru-bipyridine complex composite film with poly(Na styrenesulfonate) in KNO<sub>3</sub> solution)
- IT 44824-14-8  
RL: PRP (Properties); **RCT (Reactant)**; RACT (Reactant or reagent)  
(electrodeposition of WO<sub>3</sub>/Ru-bipyridine complex composite film from colloidal solution containing peroxotungstic acid and Ru-bipyridine complex)
- IT 50926-11-9, Ito  
RL: **DEV (Device component use)**; PRP (Properties); USES (Uses)  
(electrodeposition of WO<sub>3</sub>/Ru-bipyridine complex composite film on ITO from colloidal solution containing peroxotungstic acid and Ru-bipyridine complex)
- IT 106-44-5, p-Cresol, uses  
RL: NUU (Other use, unclassified); PRP (Properties); USES (Uses)  
(photocurrent of WO<sub>3</sub>/Ru-bipyridine complex composite film with poly(Na styrenesulfonate) on ITO electrode in KNO<sub>3</sub> solution with and without)
- IT 1314-35-8P, Tungsten oxide wo<sub>3</sub>, properties  
RL: CPS (Chemical process); PEP (Physical, engineering or chemical process); PNU (Preparation, unclassified); PRP (Properties); **PREP (Preparation)**; PROC (Process)  
(preparation by electrodeposition of colloidal solution containing peroxotungstic acid and Ru-bipyridine and photoelectrochem. properties of WO<sub>3</sub>/Ru-bipyridine complex composite film stabilized by poly(Na styrenesulfonate))
- IT 62744-35-8, Poly(sodium styrenesulfonate)

RL: NUU (Other use, unclassified); USES (Uses)

(preparation by electrodeposition of colloidal solution containing peroxotungstic

acid and Ru-bipyridine and photoelectrochem. properties of WO<sub>3</sub>/Ru-bipyridine complex composite film stabilized by poly(Na styrenesulfonate))

IT 15158-62-0P, Tris(2,2'-bipyridine)ruthenium(2+)

RL: PNU (Preparation, unclassified); PRP (Properties); PREP (Preparation)

(preparation by electrodeposition of colloidal solution containing peroxotungstic

acid and Ru-bipyridine and photoelectrochem. properties of WO<sub>3</sub>/Ru-bipyridine complex composite film stabilized by poly(Na styrenesulfonate))

RE.CNT 18 THERE ARE 18 CITED REFERENCES AVAILABLE FOR THIS RECORD

RE

- (1) Bechinger, C; Nature 1996, V383, P608 CAPLUS
- (2) Colton, R; J Appl Phys 1978, V49, P409 CAPLUS
- (3) Gallagher, L; J Am Chem Soc 2001, V123, P5308 CAPLUS
- (4) Giraudeau, A; J Am Chem Soc 1980, V102, P5137 CAPLUS
- (5) Hirata, J; J Chem Soc-Faraday Trans 1996, V92, P969 CAPLUS
- (6) Kurimura, Y; Bull Chem Soc Jpn 1982, V55, P55 CAPLUS
- (7) Lin, R; Molecular Electronics 1993, V1, P207 CAPLUS
- (8) Nagasu, M; J Appl Phys 1992, V71, P398 CAPLUS
- (9) O'Regan, B; Nature 1991, V353, P737 CAPLUS
- (10) Santato, C; J Am Chem Soc 2001, V123, P10639 CAPLUS
- (11) Santato, C; J Phys Chem B 2001, V105, P936 CAPLUS
- (12) Sayama, K; Chem Commun 2001, P2416 CAPLUS
- (13) Shen, P; J Mater Chem 1992, V2, P1141 CAPLUS
- (14) Trammell, S; J Phys Chem B 1999, V103, P104 CAPLUS
- (15) Yagi, M; Chem Rev 2001, V101, P21 CAPLUS
- (16) Yagi, M; J Chem Soc, Faraday Trans 1997, V93, P3125 CAPLUS
- (17) Yamanaka, K; Jpn J Appl Phys Part 1-Regul Pap Short Notes Rev Pap 1986, V25, P1420 CAPLUS
- (18) Yous, B; Mater Res Bull 1984, V19, P1349 CAPLUS

L85 ANSWER 18 OF 29 WPIX COPYRIGHT 2004 THOMSON DERWENT on STN

AN 2002-097294 [13] WPIX

DNN N2002-071920 DNC C2002-030209

TI **Electroluminescent** device for use in the development of organic semiconductor employs clay nanocomposite emissive layer spin coated with organic **luminescent** material/clay nanocomposite.

DC A18 A26 A85 E19 L03 X26

IN LEE, T U; PARK, O O; LEE, T; PARK, O

PA (KOAD) KOREA ADV INST SCI & TECHNOLOGY; (LEET-I) LEE T; (PARK-I) PARK O  
CYC 4

PI WO 2001072925 A1 20011004 (200213)\* EN 20p C09K011-00  
W: DE JP KR US

KR 2001095437 A 20011107 (200226) C09K011-00

US 2002041151 A1 20020411 (200227) H05B033-20

DE 10191387 T 20020801 (200258) C09K011-00

KR 2002026860 A 20020412 (200267) C09K011-00

US 6593688 B2 20030715 (200348) H05B033-20

JP 2003528971 W 20030930 (200365) 18p C09K011-06

US 2003211359 A1 20031113 (200382) H05B033-14

ADT WO 2001072925 A1 WO 2001-KR534 20010330; KR 2001095437 A KR 2000-16466 20000330; US 2002041151 A1 Cont of WO 2001-KR534 20010330, US 2001-995950 20011127; DE 10191387 T DE 2001-10191387 20010330, WO 2001-KR534 20010330; KR 2002026860 A KR 2001-705364 20010427; US 6593688 B2 Cont of WO 2001-KR534 20010330, US 2001-995950 20011127; JP 2003528971 W JP 2001-571842 20010330, WO 2001-KR534 20010330; US 2003211359 A1 Cont of WO 2001-KR534 20010330, Cont of US 2001-995950 20011127, US 2003-442861 20030520

FDT DE 10191387 T Based on WO 2001072925; JP 2003528971 W Based on WO 2001072925; US 2003211359 A1 Cont of US 6593688

PRAI KR 2000-16466 20000330

IC ICM C09K011-00; C09K011-06; H05B033-14; H05B033-20  
ICS H05B033-02; H05B033-10; H05B033-22; H05B033-26; H05B033-28

AB WO 200172925 A UPAB: 20020226

NOVELTY - An **electroluminescent** device comprises a transparent substrate (1) and a semitransparent electrode (2) deposited on the substrate. A clay nanocomposite emissive layer (4) spin coated with organic **luminescent** material/clay nanocomposite is positioned on the semitransparent electrode. A metal electrode (6) is deposited on the clay nanocomposite emissive layer.

DETAILED DESCRIPTION - An INDEPENDENT CLAIM is also included for an organic **luminescent** material/clay nanocomposite in a form of quantum well, by blending an organic **luminescent** material and a nanoclay.

USE - For use in the development of organic semiconductor.

ADVANTAGE - The inventive **EL** device has improved **luminescent** efficiency and stability.

DESCRIPTION OF DRAWING(S) - The figure shows a cross-sectional view of the **EL** device.

Transparent substrate 1  
Semitransparent electrode 2  
Hole transporting layer 3  
Clay nanocomposite emissive layer 4  
Electron transporting layer 5  
Metal electrode 6

Dwg.2/4

FS CPI EPI

FA AB; GI; DCN

MC CPI: A12-E11C; E05-B03; E06-H; E07-H; E08-B; E08-C01; E08-D02; E10-B01A4; E10-B04A2; E31-P02D; E31-P05B; L03-C04A; L03-D01D  
EPI: X26-J

L85 ANSWER 19 OF 29 CAPLUS COPYRIGHT 2004 ACS on STN

AN 2001:790479 CAPLUS

DN 136:86162

ED Entered STN: 31 Oct 2001

TI The role of ruthenium and rhenium diimine complexes in conjugated polymers that exhibit interesting opto-**electronic** properties

AU Ng, Po King; Gong, Xiong; Chan, Suk Hang; Lam, Lillian Sze Man; Chan, Wai Kin

CS Department of Chemistry, University of Hong Kong, Hong Kong, Hong Kong

SO Chemistry--A European Journal (2001), 7(20), 4358-4367  
CODEN: CEUJED; ISSN: 0947-6539

PB Wiley-VCH Verlag GmbH

DT Journal

- LA English
- CC 35-6 (Chemistry of Synthetic High Polymers)  
Section cross-reference(s): 73, 76
- AB This paper reports the synthesis and opto-electronic properties of different conjugated polymers that contain the diimine complexes of ruthenium or rhenium. Conjugated poly(phenylene vinylene)s that contain aromatic 1.3.4-oxadiazole and 2.2'-bipyridine units on the main chain were synthesized by the palladium catalyzed olefinic coupling reaction. Other types of polymers based on 1.10-phenanthroline bis(2.2-bipyridyl) ruthenium(II) or chloro tricarbonyl rhenium(I) complexes were also synthesized by the same reaction. In general, these polymers exhibit two absorption bands due to the  $\pi - \pi^*$  transition of the conjugated main chain and the  $d - \pi^*$  metal-to-ligand charge-transfer transition of the metal complex. As a result, the photosensitivity of the polymers beyond 500 nm was enhanced. Charge-carrier mobility measurements showed that the presence of metal complexes could facilitate the charge-transport process, and the enhancement in carrier mobility was dependent on the metal content in the polymer. In addition, we have also demonstrated that the ruthenium complex could act as both photosensitizer and light emitter. Photovoltaic cells were constructed, and they were subjected to irradiation with a xenon arc lamp. Under illumination, the short circuit current and the open circuit voltage were measured to be 0.05 mA cm<sup>-2</sup> and 0.35 V, resp. The polymers were fabricated into single-layer emitting devices, and light emission was observed when the device was subjected to forward bias. The maximum luminance was determined to be 300 cd m<sup>-2</sup>, and the external quantum efficiency was approx. 0.05 to 0.2%. Although the efficiency was relatively low when compared with other devices based on organic materials, we have demonstrated the first examples of using transition metal complexes for both photovoltaic and light-emitting applications.
- ST polyphenylene vinylene diimine complex ruthenium rhenium prepn sensitizer luminescence
- IT Polymers, preparation  
RL: PRP (Properties); SPN (Synthetic preparation); PREP (Preparation)  
(conjugated; role of ruthenium and rhenium diimine complexes in conjugated polymers)
- IT Charge transfer complexes  
RL: PRP (Properties)  
(intramol.; role of ruthenium and rhenium diimine complexes in conjugated polymers)
- IT Hole mobility  
(mobilities of; role of ruthenium and rhenium diimine complexes in conjugated polymers)
- IT Cyclic voltammetry  
Electric current-potential relationship  
Luminescence  
Luminescence, electroluminescence  
(role of ruthenium and rhenium diimine complexes in conjugated polymers)
- IT Poly(arylenealkenylenes)  
RL: PRP (Properties); SPN (Synthetic preparation); PREP (Preparation)  
(role of ruthenium and rhenium diimine complexes in conjugated polymers)



- IT **Electroluminescent devices**  
(single-layer; role of ruthenium and rhenium diimine complexes in conjugated polymers)
- IT 50926-11-9, ITO  
RL: **DEV (Device component use)**; **USES (Uses)**  
(electrode; role of ruthenium and rhenium diimine complexes in conjugated polymers)
- IT 1802-30-8, 2,2'-Bipyridine-5,5'-dicarboxylic acid 6813-38-3, 2,2'-Bipyridine-4,4'-dicarboxylic acid  
RL: **RCT (Reactant)**; **RAC (Reactant or reagent)**  
(ligand synthesis; role of ruthenium and rhenium diimine complexes in conjugated polymers)
- IT 50907-23-8P  
RL: **RCT (Reactant)**; **SPN (Synthetic preparation)**; **PREP (Preparation)**; **RAC (Reactant or reagent)**  
(ligand synthesis; role of ruthenium and rhenium diimine complexes in conjugated polymers)
- IT 385767-23-7  
RL: **RCT (Reactant)**; **RAC (Reactant or reagent)**  
(ligand; role of ruthenium and rhenium diimine complexes in conjugated polymers)
- IT 385767-22-6P  
RL: **RCT (Reactant)**; **SPN (Synthetic preparation)**; **PREP (Preparation)**; **RAC (Reactant or reagent)**  
(ligand; role of ruthenium and rhenium diimine complexes in conjugated polymers)
- IT 202667-34-3P 264916-72-5P 386706-87-2P 386706-89-4P  
RL: **RCT (Reactant)**; **SPN (Synthetic preparation)**; **PREP (Preparation)**; **RAC (Reactant or reagent)**  
(metal complex monomer; role of ruthenium and rhenium diimine complexes in conjugated polymers)
- IT 2923-28-6, Silver trifluoromethanesulfonate 19542-80-4  
RL: **RCT (Reactant)**; **RAC (Reactant or reagent)**  
(monomer synthesis; role of ruthenium and rhenium diimine complexes in conjugated polymers)
- IT 216964-54-4P  
RL: **RCT (Reactant)**; **SPN (Synthetic preparation)**; **PREP (Preparation)**; **RAC (Reactant or reagent)**  
(monomer synthesis; role of ruthenium and rhenium diimine complexes in conjugated polymers)
- IT 78-30-8P, Tri-o-tolylphosphate 102-82-9P, Tri-n-butylamine  
RL: **PRP (Properties)**; **SPN (Synthetic preparation)**; **PREP (Preparation)**  
(polymerization catalyst; role of ruthenium and rhenium diimine complexes in conjugated polymers)
- IT 385767-24-8P 385767-25-9P 385767-26-0P  
386706-90-7P 386706-91-8P 386706-92-9P  
386706-94-1P 386706-95-2P 386706-97-4P  
386706-99-6P  
RL: **PRP (Properties)**; **SPN (Synthetic preparation)**; **PREP (Preparation)**  
(role of ruthenium and rhenium diimine complexes in conjugated polymers)
- IT 623-00-7, 1-Bromo-4-Cyanobenzene 14099-01-5, Rhenium pentacarbonyl chloride 17084-13-8, Potassium hexafluorophosphate 26628-22-8, Sodium

azide 100125-12-0, 3,8-Dibromo-1,10-phenanthroline

RL: RCT (Reactant); RACT (Reactant or reagent)

(role of ruthenium and rhenium diimine complexes in conjugated polymers)

RE.CNT 63 THERE ARE 63 CITED REFERENCES AVAILABLE FOR THIS RECORD

RE

- (1) Anon; Handbook of Conducting Polymers 2nd ed 1998
- (2) Anon; Macromolecule-Metal Complexes 1996
- (3) Anon; Semiconducting Polymers-Chemistry, Physics and Engineering 2000
- (4) Baldo, M; Appl Phys Lett 1999, V75, P4 CAPLUS
- (5) Baldo, M; Nature 1998, V395, P151 CAPLUS
- (6) Bao, Z; Appl Phys Lett 1996, V69, P4108 CAPLUS
- (7) Borsenberger, P; J Chem Phys 1991, V94, P5447 CAPLUS
- (8) Buchwald, E; Adv Mater 1995, V7, P839 CAPLUS
- (9) Burroughes, J; Nature 1990, V347, P539 CAPLUS
- (10) Cameron, C; Chem Commun 1997, P303 CAPLUS
- (11) Chan, W; Appl Phys Lett 1997, V71, P2919 CAPLUS
- (12) Chan, W; Appl Phys Lett 1999, V75, P3920 CAPLUS
- (13) Chan, W; J Mater Chem 1999, V9, P2103 CAPLUS
- (14) Elliott, C; J Am Chem Soc 1982, V104, P7519 CAPLUS
- (15) Gong, X; Adv Mater 1998, V10, P1337 CAPLUS
- (16) Greiner, A; Polymer 1991, V32, P1857 CAPLUS
- (17) Halls, J; Appl Phys Lett 1996, V68, P3120 CAPLUS
- (18) Halls, J; Nature 1995, V376, P498 CAPLUS
- (19) Handy, E; J Am Chem Soc 1999, V121, P3525 CAPLUS
- (20) Hide, F; Science 1996, V273, P1833 CAPLUS
- (21) Jones, W; Multimetallic and Macromolecular Inorganic Photochemistry 1999, P1 CAPLUS
- (22) Juris, A; Coord Chem Rev 1988, V84, P85 CAPLUS
- (23) Kalyanasundaram, K; Coord Chem Rev 1982, V46, P159 CAPLUS
- (24) Kryukov, A; Thin Solid Films 1992, V209, P84 CAPLUS
- (25) Lam, L; Macromol Rapid Commun 2000, V21, P1081 CAPLUS
- (26) Lee, J; Chem Mater 1997, V9, P1710 CAPLUS
- (27) Ley, K; Coord Chem Rev 1998, V171, P287 CAPLUS
- (28) Ley, K; J Am Chem Soc 1997, V119, P3423 CAPLUS
- (29) Lyons, C; J Am Chem Soc 1998, V120, P12100 CAPLUS
- (30) Ma, Y; Chem Commun 1998, P2491 CAPLUS
- (31) Ma, Y; Synth Met 1998, V94, P245 CAPLUS
- (32) Ng, P; Macromol Rapid Commun 1997, V18, P1009 CAPLUS
- (33) Ng, W; Chem Mater 1999, V11, P1165 CAPLUS
- (34) Oki, A; Syn Commun 1995, V25, P4093 CAPLUS
- (35) O'Brien, D; Appl Phys Lett 1999, V74, P442 CAPLUS
- (36) Pei, Q; Adv Mater 1995, V7, P559 CAPLUS
- (37) Peng, Z; Adv Mater 1998, V10, P680 CAPLUS
- (38) Peng, Z; Appl Phys Lett 1996, V69, P4002 CAPLUS
- (39) Rasmussen, S; Inorg Chem 1996, V35, P3449 CAPLUS
- (40) Schulz, B; Adv Mater 1997, V9, P601 CAPLUS
- (41) Sirringhaus, H; Science 1998, V280, P1741 CAPLUS
- (42) Spear, W; Proc Phys Soc 1975, V70, P669
- (43) Strey, B; J Polym Sci Polym Lett Ed 1965, P265
- (44) Tamoto, N; Chem Mater 1997, V9, P1077 CAPLUS
- (45) Tao, X; Appl Phys Lett 1997, V70, P1503 CAPLUS
- (46) Tessler, N; Nature 1996, V382, P695 CAPLUS
- (47) Tokuhisa, H; Appl Phys Lett 1995, V66, P3433 CAPLUS
- (48) Trouillet, L; Chem Mater 2000, V12, P1611 CAPLUS

- (49) Tzalis, D; Tetrahedron Lett 1995, V36, P3489 CAPLUS
- (50) Wang, B; J Am Chem Soc 1997, V119, P12 CAPLUS
- (51) Wang, Q; J Am Chem Soc 1998, V120, P12860 CAPLUS
- (52) Wolfbauer, G; J Am Chem Soc 2000, V122, P130 CAPLUS
- (53) Wong, C; Adv Mater 1999, V11, P455 CAPLUS
- (54) Xie, P; Inorg Chim Acta 2000, V308, P73 CAPLUS
- (55) Yam, V; Chem Commun 2000, P53
- (56) Yanagida, M; J Chem Soc 2000, P2817 CAPLUS
- (57) Yang, Y; Nature 1994, V372, P344 CAPLUS
- (58) Yin, S; Synth Met 1998, V93, P193 CAPLUS
- (59) Yu, G; Appl Phys Lett 1994, V64, P1540 CAPLUS
- (60) Yu, G; J Appl Phys 1995, V78, P4510 CAPLUS
- (61) Yu, S; Macromolecules 1998, V31, P5639 CAPLUS
- (62) Yu, S; Macromolecules 1999, V32, P5251 CAPLUS
- (63) Yu, S; Macromolecules 2000, V33, P3529

L85 ANSWER 20 OF 29 CAPLUS COPYRIGHT 2004 ACS on STN

AN 2000:723659 CAPLUS

DN 133:328334

ED Entered STN: 13 Oct 2000

TI Multi-component multiphase type polymer material and its use in functional element.

IN Hiraoka, Toshiro; Asakawa, Koji

PA Toshiba Corp., Japan

SO Jpn. Kokai Tokkyo Koho, 26 pp.

CODEN: JKXXAF

DT Patent

LA Japanese

IC ICM H01L051-00

ICS C08F291-00; C08F297-00; H01L031-04; H01L033-00

CC 76-3 (Electric Phenomena)

Section cross-reference(s): 73

FAN.CNT 1

	PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
	-----	----	-----	-----	-----
PI	JP 2000286479	A2	20001013	JP 1999-87094	19990329
	US 6391471	B1	20020521	US 2000-536684	20000328
PRAI	JP 1999-87094	A	19990329		

AB The polymer material has 3-dimensionally continuous nanophase separation structure and comprises phase A which is an aggregate of hole- or electron-conductive polymer chain and phase B which is an aggregate of another hole- or electron conductive polymer chain, and the two phases are chemical bonded at the interfaces. The functional element comprises the above material sandwiched between a pair of electrode. Preferably, the polymer material is A-B or B-A-B type block copolymers. The functional elements are useful in solar cells, photoelec. converters, capacitors, and other **electronic** devices.

ST conductive block copolymer **electronic** device

IT Capacitors

Electrochromic devices

**Electroluminescent** devices

Secondary batteries

Transistors

(based on conductive conjugated block copolymers)

IT Silsesquioxanes

RL: DEV (Device component use); SPN (Synthetic preparation);  
PREP (Preparation); USES (Uses)  
(based on conductive conjugated block copolymers)

IT Photoelectric devices  
(converters; based on conductive conjugated block copolymers)

IT 113782-99-3P 302841-76-5P  
RL: DEV (Device component use); SPN (Synthetic preparation);  
PREP (Preparation); USES (Uses)  
(capacitors containing conjugated conductive block copolymers)

IT 302841-70-9P  
RL: DEV (Device component use); SPN (Synthetic preparation);  
PREP (Preparation); USES (Uses)  
(diblock; electrochromic devices containing conjugated conductive block copolymers)

IT 302841-63-0P  
RL: DEV (Device component use); SPN (Synthetic preparation);  
PREP (Preparation); USES (Uses)  
(diblock; electroluminescent devices containing conjugated conductive block copolymers)

IT 302841-68-5P 302841-69-6P  
RL: DEV (Device component use); SPN (Synthetic preparation);  
PREP (Preparation); USES (Uses)  
(electroluminescent devices containing conjugated conductive block copolymers)

IT 302841-77-6DP, block polymer with silsesquioxane  
RL: DEV (Device component use); SPN (Synthetic preparation);  
PREP (Preparation); USES (Uses)  
(electronic devices containing conjugated conductive block copolymers)

IT 302896-97-5P  
RL: DEV (Device component use); SPN (Synthetic preparation);  
PREP (Preparation); USES (Uses)  
(photoelec. converters containing conjugated conductive block copolymers)

IT 302841-72-1P  
RL: DEV (Device component use); SPN (Synthetic preparation);  
PREP (Preparation); USES (Uses)  
(triblock; batteries containing conjugated conductive block copolymers)

IT 302841-74-3P 302841-75-4P  
RL: DEV (Device component use); SPN (Synthetic preparation);  
PREP (Preparation); USES (Uses)  
(triblock; capacitors containing conjugated conductive block copolymers)

IT 302841-67-4P  
RL: DEV (Device component use); SPN (Synthetic preparation);  
PREP (Preparation); USES (Uses)  
(triblock; electroluminescent devices containing conjugated conductive block copolymers)

L85 ANSWER 21 OF 29 CAPLUS COPYRIGHT 2004 ACS on STN  
AN 2000:573593 CAPLUS  
DN 133:200910  
ED Entered STN: 18 Aug 2000  
TI Fabrication of electronic devices containing a columnar discotic phase  
IN Lupo, Donald; Yasuda, Akio; Nelles, Gabriele  
PA Sony International (Europe) G.m.b.H., Germany

SO Eur. Pat. Appl., 10 pp.

CODEN: EPXXDW

DT Patent

LA English

IC ICM H01L051-20

ICS H01L051-30

CC 74-13 (Radiation Chemistry, Photochemistry, and Photographic and Other Reprographic Processes)

Section cross-reference(s): 35, 52, 76

FAN.CNT 1

	PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
PI	EP 1028475	A1	20000816	EP 1999-102473	19990209
	R: AT, BE, CH, DE, DK, ES, FR, GB, GR, IT, LI, LU, NL, SE, MC, PT, IE, SI, LT, LV, FI, RO				
	US 6281430	B1	20010828	US 2000-500765	20000208
	JP 2000232232	A2	20000822	JP 2000-38134	20000209
PRAI	EP 1999-102473	A	19990209		

AB An **electronic** device comprising two adjacent regions of materials with different elec. properties was characterized in that one of the regions is formed by a columnar structure of a discotic liquid crystal material, said structure having interspaces defined between columns of said discotic liquid material, said interspaces being part of the other region and comprising a 2nd material having elec. properties and conductivity type different from those of said discotic liquid crystal. The invention also relates to a method for producing such an **electronic** structure. This **electronic** structure may be used in optoelectronic devices, e.g. solar cells.

ST **electronic** device fabrication discotic mesophase; solar cell fabrication; photodetector fabrication; LED fabrication; electrochromic device fabrication; phthalocyanine crosslinking **electronic** device; triphenylene **electronic** device

IT Liquid crystals  
(discotic; fabrication of **electronic** devices containing columnar discotic phase)

IT Electrochromic devices  
Electroluminescent devices  
Electronic device fabrication  
Optical detectors  
Optical imaging sensors  
Optoelectronic semiconductor devices  
Photoelectric devices  
Solar cells  
(fabrication of **electronic** devices containing columnar discotic phase)

IT Amorphous materials  
Chemisorption  
Crosslinking  
Solvent effect  
(in fabrication of **electronic** devices containing columnar discotic phase)

IT Metallophthalocyanines  
Polyoxadiazoles  
RL: DEV (Device component use); PEP (Physical, engineering or chemical process); PROC (Process); USES (Uses)

(in fabrication of **electronic** devices containing columnar discotic phase)

IT 217-59-4D, Triphenylene, derivs. 1493-13-6D, Trifluoromethylsulfonic acid, phthalocyanine compds. 7429-90-5, Aluminum, processes 7789-24-4, Lithium fluoride, processes 95270-88-5D, Polyfluorene, alkyl derivs.  
RL: **DEV (Device component use)**; PEP (Physical, engineering or chemical process); PROC (Process); USES (Uses)  
(in fabrication of **electronic** devices containing columnar discotic phase)

IT 288851-14-9P  
RL: **DEV (Device component use)**; PEP (Physical, engineering or chemical process); SPN (Synthetic preparation); **PREP (Preparation)**; PROC (Process); USES (Uses)  
(in fabrication of **electronic** devices containing columnar discotic phase)

IT 288851-16-1P  
RL: **DEV (Device component use)**; SPN (Synthetic preparation); **PREP (Preparation)**; USES (Uses)  
(in fabrication of **electronic** devices containing columnar discotic phase)

IT 108-88-3, Toluene, processes 108-94-1, Cyclohexanone, processes 288851-13-8 288851-15-0  
RL: NUU (Other use, unclassified); PEP (Physical, engineering or chemical process); PROC (Process); USES (Uses)  
(in fabrication of **electronic** devices containing columnar discotic phase)

IT 50926-11-9, Indium tin oxide  
RL: **DEV (Device component use)**; PEP (Physical, engineering or chemical process); PROC (Process); USES (Uses)  
(substrates; in fabrication of **electronic** devices containing columnar discotic phase)

RE.CNT 5 THERE ARE 5 CITED REFERENCES AVAILABLE FOR THIS RECORD  
RE  
(1) Antohe, S; JOURNAL DE PHYSIQUE III 1996, V6(8), P1133 CAPLUS  
(2) Basf Ag; DE 19543637 A 1997 CAPLUS  
(3) Haeussling, L; US 5683833 A 1997 CAPLUS  
(4) Tokuhisa, H; APPLIED PHYSICS LETTERS 1998, V72(21), P2639 CAPLUS  
(5) Univ Leeds; WO 9636082 A 1996 CAPLUS

L85 ANSWER 22 OF 29 WPIX COPYRIGHT 2004 THOMSON DERWENT on STN  
AN 2000-387223 [33] WPIX  
DNN N2000-289909 DNC C2000-117459  
TI Materials for use in **electroluminescent** devices comprises an organic **complex** of a transition **metal**, lanthanide or an actinide.  
DC A14 A26 A85 E19 L03 U11 U14 X12 X26  
IN KATHIRGAMANATHAN, P  
PA (UYSB-N) UNIV SOUTH BANK ENTERPRISES LTD  
CYC 88  
PI WO 2000026323 A1 20000511 (200033)\* EN 25p C09K011-06  
RW: AT BE CH CY DE DK EA ES FI FR GB GH GM GR IE IT KE LS LU MC MW NL  
OA PT SD SE SL SZ TZ UG ZW  
W: AE AL AM AT AU AZ BA BB BG BR BY CA CH CN CU CZ DE DK EE ES FI GB  
GD GE GH GM HR HU ID IL IN IS JP KE KG KP KR KZ LC LK LR LS LT LU  
LV MD MG MK MN MW MX NO NZ PL PT RO RU SD SE SG SI SK SL TJ TM TR

TT UA UG US UZ VN YU ZA ZW  
AU 2000010562 A 20000522 (200040)  
EP 1131388 A1 20010912 (200155) EN C09K011-06  
R: AL AT BE CH CY DE DK ES FI FR GB GR IE IT LI LT LU LV MC MK NL PT  
SE SI  
BR 9915252 A 20011204 (200203) C09K011-06  
KR 2001080930 A 20010825 (200215) C09K011-07  
CN 1325431 A 20011205 (200223) C09K011-06  
JP 2002528633 W 20020903 (200273) 24p C09K011-06  
AU 754481 B 20021114 (200303) C09K011-06  
MX 2001004402 A1 20020301 (200362) C09K011-06  
ADT WO 2000026323 A1 WO 1999-GB3619 19991102; AU 2000010562 A AU 2000-10562  
19991102; EP 1131388 A1 EP 1999-954123 19991102, WO 1999-GB3619 19991102;  
BR 9915252 A BR 1999-15252 19991102, WO 1999-GB3619 19991102; KR  
2001080930 A KR 2001-705447 20010430; CN 1325431 A CN 1999-812949  
19991102; JP 2002528633 W WO 1999-GB3619 19991102, JP 2000-579697  
19991102; AU 754481 B AU 2000-10562 19991102; MX 2001004402 A1 WO  
1999-GB3619 19991102, MX 2001-4402 20010502  
FDT AU 2000010562 A Based on WO 2000026323; EP 1131388 A1 Based on WO  
2000026323; BR 9915252 A Based on WO 2000026323; JP 2002528633 W Based on  
WO 2000026323; AU 754481 B Previous Publ. AU 2000010562, Based on WO  
2000026323; MX 2001004402 A1 Based on WO 2000026323  
PRAI GB 1998-23761 19981102  
IC ICM C09K011-06; C09K011-07  
ICS C07C049-92; C07D213-50; C07D317-04; C07F005-00; H01L051-20;  
H05B033-14; H05B033-22  
AB WO 200026323 A UPAB: 20000712  
NOVELTY - Photoluminescent and **electroluminescent** materials  
comprising an organic **complex** of a transition **metal**,  
lanthanide or an actinide and an organic ligand are new. Photoluminescent  
materials emit light in the blue or purplish blue spectrum,  
**electroluminescent** materials also emits light in the same spectrum  
when electric current is passed through it.  
DETAILED DESCRIPTION - INDEPENDENT CLAIMS are also included for:  
(i) a composition which comprises an inert **polymer** and  
**electroluminescent** materials (5 - 95 weight%); and  
(ii) an **electroluminescent** device which comprises  
**electroluminescent** materials deposited on a transparent substrate.  
USE - To form **electroluminescent** devices(claimed).  
ADVANTAGE - The compounds are stable. The hole transporting layer  
blocks the electrons from moving into the electrode without recombining  
with the holes.  
Dwg.0/6  
FS CPI EPI  
FA AB; DCN  
MC CPI: A12-E11; E24-A03; L03-C04; L03-D01D  
EPI: U11-A15; U14-J02A; X12-D02A1; X26-J  
L85 ANSWER 23 OF 29 WPIX COPYRIGHT 2004 THOMSON DERWENT on STN  
AN 2000-126831 [11] WPIX  
CR 1996-455560 [45]; 1998-207014 [18]; 2000-365733 [31]  
DNN N2000-095561 DNC C2000-038732  
TI Device used for detecting analytes in fluid which includes gases, vapors  
and liquids.  
DC A35 B04 D16 D25 J04 K07 S03

IN BRIGLIN, S; DOLEMAN, B J; LEWIS, N S; SEVERIN, E J  
PA (CALY) CALIFORNIA INST OF TECHNOLOGY  
CYC 87  
PI WO 2000000808 A2 20000106 (200011)\* EN 48p G01N000-00  
RW: AT BE CH CY DE DK EA ES FI FR GB GH GM GR IE IT KE LS LU MC MW NL  
OA PT SD SE SL SZ UG ZW  
W: AE AL AM AT AU AZ BA BB BG BR BY CA CH CN CU CZ DE DK EE ES FI GB  
GD GE GH GM HR HU ID IL IN IS JP KE KG KP KR KZ LC LK LR LS LT LU  
LV MD MG MK MN MW MX NO NZ PL PT RO RU SD SE SG SI SK SL TJ TM TR  
TT UA UG US UZ VN YU ZA ZW  
AU 9948210 A 20000117 (200026)  
EP 1084390 A2 20010321 (200117) EN G01N001-00  
R: AL AT BE CH CY DE DK ES FI FR GB GR IE IT LI LT LU LV MC MK NL PT  
RO SE SI  
US 6537498 B1 20030325 (200325) G01N027-00  
US 2003159927 A1 20030828 (200357)# G01N027-26  
ADT WO 2000000808 A2 WO 1999-US12904 19990608; AU 9948210 A AU 1999-48210  
19990609; EP 1084390 A2 EP 1999-931777 19990608, WO 1999-US12904 19990608;  
US 6537498 B1 Cont of US 1995-410809 19950327, Cont of US 1996-689227  
19960807, CIP of US 1997-986500 19971208, Provisional US 1998-88680P  
19980609, Provisional US 1999-118833P 19990205, US 1999-328871 19990608;  
US 2003159927 A1 Cont of US 1995-410809 19950327, Cont of US 1996-689227  
19960807, CIP of US 1997-986500 19971208, Cont of US 1999-328871 19990608,  
US 2002-266550 20021007  
FDT AU 9948210 A Based on WO 2000000808; EP 1084390 A2 Based on WO 2000000808;  
US 6537498 B1 Cont of US 5571401, Cont of US 5698089, CIP of US 6010616;  
US 2003159927 A1 Cont of US 5571401, Cont of US 5698089, CIP of US  
6010616, Cont of US 6537498  
PRAI US 1999-118833P 19990205; US 1998-88680P 19980609; US 1995-410809  
19950327; US 1996-689227 19960807; US 1997-986500 19971208; US  
1999-328871 19990608; US 2002-266550 20021007  
IC ICM G01N000-00; G01N001-00; G01N027-00; G01N027-26  
ICS G01N027-02; G01N027-327  
AB WO 2000000808 A UPAB: 20040226  
NOVELTY - A device used for detecting chemical analyte, comprises a sensor  
array with at least one sensor having regions of nonconductive and  
conductive material, and a response path through the regions of the two  
material. The two materials have different compositions and the conductive  
material contains a nanoparticle. The sensor array is connected to a  
measuring apparatus.  
DETAILED DESCRIPTION - An INDEPENDENT CLAIM is also included for an  
analyte device for detecting a chemical analyte, comprising a sensor array  
having at least one sensor comprising first and second electrical leads  
electrically connected to a chemically sensitive resistor, the resistor  
comprises a nanoparticle and provides an electrical path to the leads; and  
an **electronic measuring device** electrically connected  
to the sensor for detecting the chemical analyte.  
USE - The device is used for detecting analytes in fluid which  
includes gases, vapors and liquids. It is particularly useful in  
constructing electronic noses for analyzing complex vapors and producing a  
sample output.  
ADVANTAGE - None given.  
Dwg.0/11  
FS CPI EPI  
FA AB; DCN



MC CPI: A12-E; A12-L04; A12-W11; B04-B03C; B04-C01; B04-C02; B04-C03;  
B04-N04; B05-A03; B12-K04; D05-H09; D05-H18; J04-B; J04-C04; K07-A  
EPI: S03-E

L85 ANSWER 24 OF 29 CAPLUS COPYRIGHT 2004 ACS on STN  
AN 2000:690845 CAPLUS  
DN 134:5212  
ED Entered STN: 02 Oct 2000  
TI Synthesis of Polymers with Alternating Organosilanylene and  
Oligothienylene Units and Their Optical, Conducting, and Hole-Transporting  
Properties  
AU Ohshita, Joji; Takata, Atsuhiko; Kai, Hiroyuki; Kunai, Atsutaka;  
Komaguchi, Kenji; Shiotani, Masaru; Adachi, Akira; Sakamaki, Koichi;  
Okita, Koichi; Harima, Yutaka; Kunugi, Yoshihito; Yamashita, Kazuo;  
Ishikawa, Mitsuo  
CS Department of Applied Chemistry Faculty of Engineering, Hiroshima  
University, Higashi-Hiroshima, 739-8527, Japan  
SO Organometallics (2000), 19(22), 4492-4498  
CODEN: ORGND7; ISSN: 0276-7333  
PB American Chemical Society  
DT Journal  
LA English  
CC 35-5 (Chemistry of Synthetic High Polymers)  
Section cross-reference(s): 29, 36, 73, 76  
AB Polymers with alternating mono-, di-, or trisilanylene units and  
2,5-oligothienylene groups,  $[(\text{SiR}_2)_x(\text{C}_4\text{H}_2\text{S})_m]_n$  (R = Me, Et, x = 1-3, m =  
2-5), were synthesized and their optical, conducting, and  
hole-transporting properties were investigated. The UV absorption and  
emission maxima of the polymers shift to lower energies as the number of  
thienylene groups (m) between the silanylene units increases, while they  
are little affected by the silicon chain length (x). When the polymer  
films were exposed to  $\text{FeCl}_3$  vapor, semiconducting films with the  
conductivities of  $1.3 \times 10^{-4}$  -  $2.3 \times 10^{-1}$  S/cm were obtained.  
The conductivities tend to increase with m but decrease with increasing x.  
The double-layer-type EL devices were fabricated using some of  
the polymers (x = 1, m = 3-5; x = 2, m = 4) as the hole-transporting layer  
and tris(8-quinolinolato)aluminum(III) (Alq) as the electron-transporting-  
emitter layer. Reducing the number of m and x resulted in a high-voltage  
shift in the turn-on voltage and a decrease in the maximum c.d. of the  
device. The highest luminance of 2000 cd/m<sup>2</sup> was obtained from a device  
based on the disilanylene-tetrathienylene alternating polymer (x = 2, m =  
4).  
ST polysilane polythienylene synthesis band gap elec cond hole transport;  
**electroluminescence** device alternating organosilanylene  
oligothienylene polymer  
IT **Electronic** state  
(calculated for model compds. at PM3 level; of polymers with alternating  
organosilanylene and oligothienylene units)  
IT Crystal structure  
(of 1,2-bis(5'-bromo-2,2'-dithien-5-yl)tetraethyldisilane)  
IT Band gap  
Electric conductivity  
**Fluorescence**  
Hole transport  
UV and visible spectra

(of polymers with alternating organosilanylene and oligothienylene units)

IT Polysilanes  
 RL: PRP (Properties); SPN (Synthetic preparation); **PREP** (Preparation)  
 (polythiophene-; synthesis of polymers with alternating organosilanylene and oligothienylene units and their optical, conducting, and hole-transporting properties)

IT Conducting polymers  
**Electroluminescent devices**  
 (synthesis of polymers with alternating organosilanylene and oligothienylene units and their optical, conducting, and hole-transporting properties)

IT 7439-95-4, Magnesium, uses  
 RL: **DEV (Device component use)**; **USES (Uses)**  
 (anode; band gap energy calculated for model compds. of polymers with alternating organosilanylene and oligothienylene units at PM3 level)

IT 308284-21-1 308284-22-2 308284-23-3 308284-24-4  
 RL: PRP (Properties)  
 (band gap energy calculated for model compds. of polymers with alternating organosilanylene and oligothienylene units at PM3 level)

IT 7440-22-4, Silver, uses  
 RL: **DEV (Device component use)**; **USES (Uses)**  
 (cathode; band gap energy calculated for model compds. of polymers with alternating organosilanylene and oligothienylene units at PM3 level)

IT 175658-79-4  
 RL: PRP (Properties)  
 (crystal structure of)

IT 7705-08-0, Ferric chloride, uses  
 RL: NUU (Other use, unclassified); **USES (Uses)**  
 (dopant; synthesis of polymers with alternating organosilanylene and oligothienylene units and their optical, conducting, and hole-transporting properties)

IT 50926-11-9, ITO  
 RL: **DEV (Device component use)**; **USES (Uses)**  
 (electrode; band gap energy calculated for model compds. of polymers with alternating organosilanylene and oligothienylene units at PM3 level)

IT 2085-33-8, 8-Hydroxyquinolinealuminum  
 RL: **DEV (Device component use)**; **USES (Uses)**  
 (electron transporting-emitting layer; band gap energy calculated for model compds. of polymers with alternating organosilanylene and oligothienylene units at PM3 level)

IT 1719-53-5, Dichlorodiethylsilane 3141-27-3, 2,5-Dibromothiophene  
 RL: **RCT (Reactant)**; **RACT (Reactant or reagent)**  
 (monomer synthesis; synthesis of polymers with alternating organosilanylene and oligothienylene units and their optical, conducting, and hole-transporting properties)

IT 287936-09-8P  
 RL: **RCT (Reactant)**; SPN (Synthetic preparation); **PREP** (Preparation); **RACT (Reactant or reagent)**  
 (monomer; synthesis of polymers with alternating organosilanylene and oligothienylene units and their optical, conducting, and hole-transporting properties)

IT 175658-71-6P 175658-72-7P 175658-78-3P 244264-22-0P 244264-23-1P  
 287936-16-7P 308284-17-5P 308284-25-5P

RL: DEV (Device component use); PRP (Properties); SPN (Synthetic preparation); PREP (Preparation); USES (Uses)  
(synthesis of polymers with alternating organosilanylene and oligothienylene units and their optical, conducting, and hole-transporting properties)

IT 130904-51-7 146622-84-6

RL: PRP (Properties)

(synthesis of polymers with alternating organosilanylene and oligothienylene units and their optical, conducting, and hole-transporting properties)

IT 175658-70-5P 175658-73-8P 175658-77-2P 224433-59-4P 224433-60-7P  
224433-61-8P 244264-20-8P 244264-21-9P 263718-41-8P 308284-15-3P  
308284-16-4P 308284-18-6P 308284-19-7P 308284-26-6P

RL: PRP (Properties); SPN (Synthetic preparation); PREP (Preparation)

(synthesis of polymers with alternating organosilanylene and oligothienylene units and their optical, conducting, and hole-transporting properties)

RE.CNT 29 THERE ARE 29 CITED REFERENCES AVAILABLE FOR THIS RECORD

RE

- (1) Adachi, A; Appl Organomet Chem 1999, V13, P859 CAPLUS
- (2) Adachi, A; Synth Met 1997, V91, P333 CAPLUS
- (3) Altomare, A; J Appl Crystallogr 1994, V27, P435
- (4) Beurskens, P; The DIRDIF-94 Program System; Technical Report of the Crystallography Laboratory 1994
- (5) Chen, R; J Am Chem Soc 1997, V119, P11321 CAPLUS
- (6) Corriu, R; Chem Mater 1990, V2, P351 CAPLUS
- (7) Creagh, D; International Tables for Crystallography 1992, P200
- (8) Creagh, D; International Tables for Crystallography 1992, VC, P219
- (9) Cromer, D; International Tables for X-ray Crystallography 1974, VIV
- (10) Fang, M; Chem Lett 1994, P13 CAPLUS
- (11) Fang, M; Chem Lett 1996, P417
- (12) Fang, M; J Organomet Chem 1995, V489, P15 CAPLUS
- (13) Fang, M; Macromolecules 1996, V29, P6807 CAPLUS
- (14) Fang, M; Polymer 1996, V37, P163 CAPLUS
- (15) Harima, Y; Synth Met 1998, V98, P79 CAPLUS
- (16) Ibers, J; Acta Crystallogr 1964, V17, P781
- (17) Ishikawa, M; Handbook of Organic Conductive Molecules and Polymers, Chapter 15 1997, V2
- (18) Kunai, A; Organometallics 1996, V15, P2000 CAPLUS
- (19) Kunugi, Y; J Electroanal Chem 1996, V414, P135 CAPLUS
- (20) Manhart, S; J Organomet Chem 1999, V592, P52 CAPLUS
- (21) Molecular Structure Corp; Crystal Structure Analysis Package 1992
- (22) Ohshita, J; Acta Polym 1998, V49, P379 CAPLUS
- (23) Ohshita, J; Appl Organomet Chem 1993, V7, P269 CAPLUS
- (24) Ohshita, J; Organometallics 1994, V13, P5002 CAPLUS
- (25) Sauvajol, J; Handbook of Organic Conductive Molecules and Polymers, Chapter 14 1997
- (26) Tanaka, K; Organometallics 1994, V13, P5583
- (27) Tang, H; Electrochim Acta 1999, V44, P2579 CAPLUS
- (28) Tang, H; J Polym Sci, Part B: Polym Phys 1999, V37, P1873 CAPLUS
- (29) van Walree, C; J Am Chem Soc 1996, V118, P8395 CAPLUS

L85 ANSWER 25 OF 29 CAPLUS COPYRIGHT 2004 ACS on STN  
AN 1999:558346 CAPLUS

DN 131:322983  
ED Entered STN: 02 Sep 1999  
TI Synthesis and **electronic** properties of conjugated **polymers** based on rhenium or ruthenium dipyrrophenazine complexes  
AU Chan, Wai Kin; Ng, Po King; Gong, Xiong; Hou, Sijian  
CS Department of Chemistry, University of Hong Kong, Hong Kong  
SO Journal of Materials Chemistry (1999), 9(9), 2103-2108  
CODEN: JMACEP; ISSN: 0959-9428  
PB Royal Society of Chemistry  
DT Journal  
LA English  
CC 35-5 (Chemistry of Synthetic High Polymers)  
Section cross-reference(s): 73  
AB Two series of **luminescent** conjugated **polymers** based on rhenium(I) or ruthenium(II) dipyrrophenazine complexes were synthesized by the palladium-catalyzed coupling reaction using divinylbenzene and aromatic dibromides as the monomers. From the photoluminescence spectra, an energy transfer process between the conjugated backbone and the **metal complexes** is proposed. The ruthenium-containing **polymers** were fabricated into light emitting devices because of their better film forming qualities. The **electroluminescence** (EL) of the **polymers** originated from the emission due to the  $\pi^*-\pi$  or  $\pi^*-d$  transitions. Depending on the **metal complex** content, the **polymers** exhibit different absorption and EL spectra. The devices exhibit a turn-on voltage of 10 V and external quantum efficiency of 0.6%. From the cyclic voltammetry results, an addnl. oxidation couple was observed after the incorporation of the ruthenium complex which may contribute to the charge transport process. This was further supported by the charge mobilities measurement in which the electron and hole mobilities of the **polymers** are enhanced by the **metal complex** and are of the order of  $10^{-4} \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$ .  
ST dipyrrophenazine **metal complex** conjugated **polymer**; rhenium dipyrrophenazine complex conjugated **polymer**; ruthenium dipyrrophenazine complex conjugated **polymer**; **electronic** property **metal** dipyrrophenazine **complex polymer**; light emitting diode **metal contg polymer**  
IT **Polymers**, preparation  
RL: DEV (**Device component use**); PRP (**Properties**); SPN (**Synthetic preparation**); PREP (**Preparation**); USES (**Uses**)  
(conjugated; synthesis and **electronic** properties of conjugated **polymers** based on rhenium or ruthenium dipyrrophenazine complexes, dibromodihexylquinoxaline and divinylbenzene)  
IT **Polymerization**  
(palladium-catalyzed coupling reaction of rhenium or ruthenium dipyrrophenazine complexes, dibromodihexylquinoxaline and divinylbenzene)  
IT Cyclic voltammetry  
**Electroluminescent devices**  
Electron mobility  
Hole mobility  
**Luminescence**  
**Luminescence, electroluminescence**

- UV and visible spectra  
(synthesis and **electronic** properties of conjugated  
**polymers** based on rhenium or ruthenium dipyrrophenazine  
complexes, dibromodihexylquinoxaline and divinylbenzene)
- IT Poly(arylenealkenylenes)  
RL: DEV (Device component use); PRP (Properties); SPN (Synthetic  
preparation); PREP (Preparation); USES (Uses)  
(synthesis and **electronic** properties of conjugated  
**polymers** based on rhenium or ruthenium dipyrrophenazine  
complexes, dibromodihexylquinoxaline and divinylbenzene)
- IT 248280-95-7P  
RL: PEP (Physical, engineering or chemical process); SPN (Synthetic  
preparation); PREP (Preparation); PROC (Process)  
(monomer; for synthesis of conjugated **polymers**)
- IT 3375-31-3  
RL: CAT (Catalyst use); USES (Uses)  
(**polymerization** catalyst; in synthesis of conjugated  
**polymers** based on rhenium or ruthenium dipyrrophenazine  
complexes, dibromodihexylquinoxaline and divinylbenzene)
- IT 200503-12-4  
RL: RCT (Reactant); RACT (Reactant or reagent)  
(reactant; in synthesis of rhenium complex as monomer for preparation of  
conjugated **polymers**)
- IT 14099-01-5, Pentacarbonylrhenium chloride  
RL: RCT (Reactant); RACT (Reactant or reagent)  
(reactant; in synthesis of rhenium phenazine complex as monomer for  
preparation of conjugated **polymers**)
- IT 248243-63-2P  
RL: DEV (Device component use); PRP (Properties); SPN (Synthetic  
preparation); PREP (Preparation); USES (Uses)  
(synthesis and **electronic** properties of conjugated  
**polymers** based on rhenium or ruthenium dipyrrophenazine  
complexes, dibromodihexylquinoxaline and divinylbenzene)
- IT 248243-62-1P 248243-64-3P 248280-96-8P  
248280-97-9P  
RL: PRP (Properties); SPN (Synthetic preparation); PREP  
(Preparation)  
(synthesis and **electronic** properties of conjugated  
**polymers** based on rhenium or ruthenium dipyrrophenazine  
complexes, dibromodihexylquinoxaline and divinylbenzene)

RE.CNT 32 THERE ARE 32 CITED REFERENCES AVAILABLE FOR THIS RECORD  
RE

- (1) Bao, Z; Macromolecules 1993, V26, P5281 CAPLUS
- (2) Borsenberger, P; J Chem Phys 1991, V94, P5447 CAPLUS
- (3) Burroughes, J; Nature 1990, V347, P539 CAPLUS
- (4) Chan, W; Appl Phys Lett 1997, V71, P2919 CAPLUS
- (5) Chan, W; Macromolecules 1995, V28, P6410 CAPLUS
- (6) Greenham, N; Nature 1995, V365, P628
- (7) Greenham, N; Nature 1995, V365, P628
- (8) Gustafsson, G; Nature 1992, V357, P477 CAPLUS
- (9) Gustafsson, G; Nature 1992, V357, P477 CAPLUS
- (10) Heck, R; Org React 1982, V27, P345 CAPLUS
- (11) Hopkins, T; Chem Mater 1996, V8, P344 CAPLUS
- (12) Hsieh, B; Adv Mater 1995, V7, P36 CAPLUS
- (13) Juris, A; Coord Chem Rev 1988, V84, P85 CAPLUS

- (14) Kalyanasundaram, K; Coord Chem Rev 1982, V46, P159 CAPLUS
- (15) Kido, J; Appl Phys Lett 1994, V65, P2124 CAPLUS
- (16) Kido, J; Appl Phys Lett 1994, V64, P815 CAPLUS
- (17) Kryukov, A; Thin Solid Films 1992, V209, P84 CAPLUS
- (18) Lee, J; Chem Mater 1997, V9, P1710 CAPLUS
- (19) Maness, K; J Am Chem Soc 1996, V118, P10609 CAPLUS
- (20) Maness, K; J Am Chem Soc 1997, V119, P3987 CAPLUS
- (21) Martelock, H; Makromol Chem 1991, V192, P967 CAPLUS
- (22) Ng, P; Macromol Rapid Commun 1997, V18, P1009 CAPLUS
- (23) Ng, W; Adv Mater 1997, V9, P716 CAPLUS
- (24) Pfister, G; Adv Phys 1978, V27, P747 CAPLUS
- (25) Pfister, G; Phys Rev B 1977, V16, P3676 CAPLUS
- (26) Scher, H; Phys Rev B 1975, V12, P2455 CAPLUS
- (27) Staring, E; Adv Mater 1994, V6, P934 CAPLUS
- (28) Strey, B; J Polym Sci A3 1965, P265
- (29) Sullivan, B; Inorg Chem 1978, V17, P3334 CAPLUS
- (30) Thomsen, D; Polym Prepr 1997, V38(1), P398 CAPLUS
- (31) Yang, Y; Appl Phys Lett 1997, V70, P1926 CAPLUS
- (32) Yu, S; Macromolecules 1998, V31, P5639 CAPLUS

L85 ANSWER 26 OF 29 CAPLUS COPYRIGHT 2004 ACS on STN

AN 1999:173784 CAPLUS

DN 130:325447

ED Entered STN: 17 Mar 1999

TI **Electronic and Light-Emitting Properties of Some Polyimides Based on Bis(2,2':6',2''-terpyridine) Ruthenium(II) Complex**

AU Ng, Wai Yue; Gong, Xiong; Chan, Wai Kin

CS Department of Chemistry, University of Hong Kong, Hong Kong

SO Chemistry of Materials (1999), 11(4), 1165-1170

CODEN: CMATEX; ISSN: 0897-4756

PB American Chemical Society

DT Journal

LA English

CC 35-5 (Chemistry of Synthetic High Polymers)

Section cross-reference(s): 36, 73

AB Novel aromatic polyimides that contain bis(2,2':6',2''-terpyridine) ruthenium(II) complex were synthesized, and their optoelectronic properties were studied. The optical absorption band at 500 nm was strongly enhanced by the presence of the ruthenium complex. As a result, the photosensitivity of the polyimides in the visible region increased, as did the photocond. The glass transition temperature of the polyimides is approx. 220° and they also exhibit modest thermal stability. The electron mobility and hole carrier mobility of the polyimides are on the order of 10<sup>-4</sup> cm<sup>2</sup> V<sup>-1</sup> s<sup>-1</sup>, which suggests that the electron-withdrawing diimide moieties play a role in the charge transport process. Emission from the **metal complexes** and charge transfer states were observed in these **polymers**. The polyimides also exhibited **electroluminescent** behavior when the **polymer** films were fabricated into single-layered test light-emitting diodes. The external quantum efficiency and maximum luminance of the devices were 0.1% and 120 cd/m<sup>2</sup>, resp.

ST polyimide terpyridine ruthenium prepn optoelectronic property; photocond charge transfer ruthenium terpyridine arom polyimide; light emitting device quantum efficiency ruthenium terpyridine polyimide

IT Polyimides, preparation

- RL: PRP (Properties); SPN (Synthetic preparation); **PREP**  
**(Preparation)**  
(aromatic, fluorine-containing, ruthenium terpyridine containing;  
**electronic** and light-emitting properties of polyimides based on  
bis(terpyridine) ruthenium(II) and aromatic dianhydrides)
- IT Polyimides, preparation  
RL: PRP (Properties); SPN (Synthetic preparation); **PREP**  
**(Preparation)**  
(aromatic, ruthenium terpyridine containing; **electronic** and  
light-emitting properties of polyimides based on bis(terpyridine)  
ruthenium(II) and aromatic dianhydrides)
- IT Charge transfer state  
Electron mobility  
Electron-hole pairs  
Electrooptical absorption  
Glass transition temperature  
Photoconductivity  
Thermal stability  
(**electronic** and light-emitting properties of polyimides based  
on bis(terpyridine) ruthenium(II) and aromatic dianhydrides)
- IT Polyimides, preparation  
RL: PRP (Properties); SPN (Synthetic preparation); **PREP**  
**(Preparation)**  
(fluorine-containing, aromatic, ruthenium terpyridine containing;  
**electronic** and light-emitting properties of polyimides based on  
bis(terpyridine) ruthenium(II) and aromatic dianhydrides)
- IT **Electroluminescent devices**  
(light-emitting diodes; **electronic** and light-emitting  
properties of polyimides based on bis(terpyridine) ruthenium(II) and  
aromatic dianhydrides)
- IT Polyimides, preparation  
Polyimides, preparation  
RL: PRP (Properties); SPN (Synthetic preparation); **PREP**  
**(Preparation)**  
(polyether-, aromatic, ruthenium terpyridine containing; **electronic**  
and light-emitting properties of polyimides based on bis(terpyridine)  
ruthenium(II) and aromatic dianhydrides)
- IT Fluoropolymers, preparation  
Polyethers, preparation  
Polyethers, preparation  
Polyketones  
Polyketones  
Polysulfones, preparation  
Polysulfones, preparation  
RL: PRP (Properties); SPN (Synthetic preparation); **PREP**  
**(Preparation)**  
(polyimide-, aromatic, ruthenium terpyridine containing; **electronic**  
and light-emitting properties of polyimides based on bis(terpyridine)  
ruthenium(II) and aromatic dianhydrides)
- IT Polyimides, preparation  
Polyimides, preparation  
RL: PRP (Properties); SPN (Synthetic preparation); **PREP**  
**(Preparation)**  
(polyketone-, aromatic, ruthenium terpyridine containing; **electronic**  
and light-emitting properties of polyimides based on bis(terpyridine)

- ruthenium(II) and aromatic dianhydrides)
- IT Polyimides, preparation  
Polyimides, preparation  
RL: PRP (Properties); SPN (Synthetic preparation); **PREP**  
(Preparation)  
(polysulfone-, aromatic, ruthenium terpyridine containing; **electronic** and light-emitting properties of polyimides based on bis(terpyridine) ruthenium(II) and aromatic dianhydrides)
- IT 17084-13-8, Potassium hexafluorophosphate (KPF6)  
RL: **RCT (Reactant)**; RACT (Reactant or reagent)  
(counterion reactant; **electronic** and light-emitting properties of polyimides based on bis(terpyridine) ruthenium(II) and aromatic dianhydrides)
- IT 7429-90-5, Aluminum, uses 50926-11-9, ITO  
RL: **DEV (Device component use)**; USES (Uses)  
(electrode; **electronic** and light-emitting properties of polyimides based on bis(terpyridine) ruthenium(II) and aromatic dianhydrides)
- IT 223921-20-8P, Bis[4'-(4-aminophenyl)-2,2':6',2''-terpyridyl]ruthenium(II) Hexafluorophosphate-pyromellitic dianhydride copolymer 223921-21-9P, 3,3',4,4'-Benzophenonetetracarboxylic dianhydride-Bis[4'-(4-aminophenyl)-2,2':6',2''-terpyridyl]ruthenium(II) Hexafluorophosphate copolymer 223921-22-0P, Bis[4'-(4-aminophenyl)-2,2':6',2''-terpyridyl]ruthenium(II) Hexafluorophosphate-4,4'-(Hexafluoroisopropylidene)diphthalic anhydride copolymer 223921-23-1P, Bis[4'-(4-aminophenyl)-2,2':6',2''-terpyridyl]ruthenium(II) Hexafluorophosphate-4,4'-Oxydiphthalic anhydride copolymer 223921-25-3P, Biphenyl tetracarboxylic dianhydride-Bis[4'-(4-aminophenyl)-2,2':6',2''-terpyridyl]ruthenium(II) Hexafluorophosphate copolymer 223921-28-6P, Bis[4'-(4-aminophenyl)-2,2':6',2''-terpyridyl]ruthenium(II) Hexafluorophosphate-3,3',4,4'-diphenyl sulfone tetracarboxylic dianhydride copolymer  
RL: PRP (Properties); SPN (Synthetic preparation); **PREP**  
(Preparation)  
(**electronic** and light-emitting properties of polyimides based on bis(terpyridine) ruthenium(II) and aromatic dianhydrides)
- IT 129077-51-6, 4'-(4-Nitrophenyl)-2,2':6',2''-terpyridine  
RL: **RCT (Reactant)**; RACT (Reactant or reagent)  
(**electronic** and light-emitting properties of polyimides based on bis(terpyridine) ruthenium(II) and aromatic dianhydrides)
- IT 178265-65-1P  
RL: **RCT (Reactant)**; SPN (Synthetic preparation); **PREP**  
(Preparation); RACT (Reactant or reagent)  
(intermediate; **electronic** and light-emitting properties of polyimides based on bis(terpyridine) ruthenium(II) and aromatic dianhydrides)
- IT 196202-22-9P, Bis[4'-(4-aminophenyl)-2,2':6',2''-terpyridyl]ruthenium(II) Hexafluorophosphate  
RL: **RCT (Reactant)**; SPN (Synthetic preparation); **PREP**  
(Preparation); RACT (Reactant or reagent)  
(monomer; **electronic** and light-emitting properties of polyimides based on bis(terpyridine) ruthenium(II) and aromatic dianhydrides)
- IT 10049-08-8, Ruthenium trichloride  
RL: **RCT (Reactant)**; RACT (Reactant or reagent)



(reactant; **electronic** and light-emitting properties of polyimides based on bis(terpyridine) ruthenium(II) and aromatic dianhydrides)

IT 7772-99-8, Tin(II) chloride, reactions

RL: RCT (Reactant); RACT (Reactant or reagent)

(reducing agent; **electronic** and light-emitting properties of polyimides based on bis(terpyridine) ruthenium(II) and aromatic dianhydrides)

RE.CNT 33 THERE ARE 33 CITED REFERENCES AVAILABLE FOR THIS RECORD

RE

- (1) Beley, M; J Chem Soc Dalton Trans 1991, P3157 CAPLUS
- (2) Borsenberger, P; J Chem Phys 1991, V94, P5447 CAPLUS
- (3) Calvert, J; J Am Chem Soc 1982, V104, P6620 CAPLUS
- (4) Chan, W; Appl Phys Lett 1997, V71, P2919 CAPLUS
- (5) Chen, T; J Am Chem Soc 1995, V117, P7295 CAPLUS
- (6) Collin, J; Inorg Chem 1991, V30, P4230 CAPLUS
- (7) Creed, D; Polym Prepr (Am Chem Soc, Div Polym Chem) 1992, V33, P855 CAPLUS
- (8) Creutz, C; J Am Chem Soc 1980, V102, P1309 CAPLUS
- (9) Freilich, S; Macromolecules 1987, V20, P973 CAPLUS
- (10) Ghosh, M; Polyimides: Fundamentals and Applications 1996
- (11) Hacker, C; Inorg Chem 1991, V30, P538
- (12) Hasegawa, M; J Polym Sci Polym Lett 1989, V27, P263 CAPLUS
- (13) Jenekhe, S; Photonic and Optoelectronic Polymers 1997, V672 CAPLUS
- (14) Kan, L; J Chem Phys 1993, V98, P3445 CAPLUS
- (15) Lee, J; Chem Mater 1997, V9, P1710 CAPLUS
- (16) Li, L; Appl Phys B 1991, V53, P279
- (17) Lytle, F; Anal Chim Acta 1971, V57, P239 CAPLUS
- (18) Mal'Tsev, E; Appl Phys Lett 1997, V71, P3480 CAPLUS
- (19) Maness, K; J Am Chem Soc 1996, V118, P10609 CAPLUS
- (20) Maness, K; J Am Chem Soc 1997, V119, P3987 CAPLUS
- (21) Mittal, K; Polyimides: Synthesis, Characterization and Applications 1984, V1 and 2
- (22) Mukkala, V; Helv Chim Acta 1993, V76, P1361 CAPLUS
- (23) Ng, P; Macromol Rapid Commun 1997, V18, P1009 CAPLUS
- (24) Ng, W; Adv Mater 1997, V9, P716 CAPLUS
- (25) Pariser, R; Polym J 1987, V19, P127 CAPLUS
- (26) Peng, X; Appl Phys Lett 1990, V57, P2013 CAPLUS
- (27) Sauvage, J; Chem Rev 1994, V94, P993 CAPLUS
- (28) Stone, M; Chem Phys Lett 1981, V79, P169 CAPLUS
- (29) van Der Auweraer, M; Adv Mater 1994, V6, P199 CAPLUS
- (30) Verbiest, T; Science 1995, V268, P1604 CAPLUS
- (31) Yu, D; J Am Chem Soc 1995, V117, P11680 CAPLUS
- (32) Yu, D; Macromolecules 1996, V29, P6139 CAPLUS
- (33) Yu, S; Macromolecules 1998, V31, P5639 CAPLUS

L85 ANSWER 27 OF 29 CAPLUS COPYRIGHT 2004 ACS on STN

AN 2000:496820 CAPLUS

DN 133:327374

ED Entered STN: 24 Jul 2000

TI Development of metal-containing polymers for optoelectronic applications

AU Chan, Wai Kin; Hou, Sijian; Ng, Po King; Wong, Chi Tak; Yu, Sze Chit

CS Dep. Chem., Univ. of Hong Kong, Hong Kong, Peop. Rep. China

SO Proceedings of SPIE-The International Society for Optical Engineering (1999), 3896 (Design, Fabrication, and Characterization of Photonic

Devices), 223-230

CODEN: PSISDG; ISSN: 0277-786X

PB SPIE-The International Society for Optical Engineering

DT Journal

LA English

CC 73-11 (Optical, Electron, and Mass Spectroscopy and Other Related Properties)

AB Most of the work in organic **electroluminescent** polymers was focused on organic conjugated polymers. However, polymers attached with transition **metal** complex have received relatively less attention. The authors synthesized and studied the light emitting properties of some **metal** containing polymers based on the polypyridine complexes of Re and Ru. These complexes exhibit long-lived excited states caused by the **metal** to ligand charge transfer transitions. By varying the structure of the ligand and/or the transition **metal**, the authors are able to fine-tune the **electronic** properties of the resulting **metal** complexes.

ST polyphenylene vinylene ruthenium bipyridine terpyridine LED

IT Polymers, properties

RL: **DEV (Device component use)**; PEP (Physical, engineering or chemical process); PRP (Properties); PROC (Process); USES (Uses) (conjugated; development of **metal**-containing polymers for optoelectronic applications)

IT **Electroluminescent** devices

**Luminescence, electroluminescence**

UV and visible spectra

(development of **metal**-containing polymers for optoelectronic applications)

IT Transition **metal** complexes

RL: **DEV (Device component use)**; PEP (Physical, engineering or chemical process); PRP (Properties); PROC (Process); USES (Uses) (development of **metal**-containing polymers for optoelectronic applications)

IT Electric current carriers

(mobility; development of **metal**-containing polymers for optoelectronic applications)

IT 92583-93-2P 193484-92-3P 193484-95-6P

RL: **DEV (Device component use)**; PEP (Physical, engineering or chemical process); PRP (Properties); SPN (Synthetic preparation); **PREP (Preparation)**; PROC (Process); USES (Uses) (development of **metal**-containing polymers for optoelectronic applications)

RE.CNT 21 THERE ARE 21 CITED REFERENCES AVAILABLE FOR THIS RECORD  
RE

- (1) Burroughes, J; Nature 1990, V347, P539 CAPLUS
- (2) Chan, W; Appl Phys Lett 1997, V71, P2919 CAPLUS
- (3) Constable, E; Adv Inorg Chem Radiochem 1986, V30, P69 CAPLUS
- (4) Constable, E; Inorg Chim Acta 1990, V178, P47 CAPLUS
- (5) Gong, X; Adv Mater 1998, V10, P1337 CAPLUS
- (6) Greenham, N; Nature 1995, V365, P628
- (7) Gustafsson, G; Nature 1992, V357, P477 CAPLUS
- (8) Heck, R; Organic Reactions 1982, V27, P345 CAPLUS
- (9) Helfrich, W; J Chem Phys 1966, V44, P2902 CAPLUS
- (10) Hopkins, T; Chem Mater 1996, V8, P344 CAPLUS
- (11) Juris, A; Coord Chem Rev 1988, V84, P85 CAPLUS

- (12) Kalyanasundaram, K; Coord Chem Rev 1982, V46, P159 CAPLUS
- (13) Kido, J; Appl Phys Lett 1994, V65, P2124 CAPLUS
- (14) Kido, J; Appl Phys Lett 1994, V64, P815 CAPLUS
- (15) Lee, J; Chem Mater 1997, V9, P1710 CAPLUS
- (16) Ng, W; Adv Mater 1997, V9, P716 CAPLUS
- (17) Sauvage, J; Chem Rev 1994, V94, P993 CAPLUS
- (18) Thomsen, D; Polymer Preprint 1997, V38(1), P398 CAPLUS
- (19) Van der Auweraer, M; Adv Mater 1994, V6, P199 CAPLUS
- (20) Wong, C; Adv Mater 1999, V11, P455 CAPLUS
- (21) Yu, S; Macromolecules 1998, V31, P5639 CAPLUS

L85 ANSWER 28 OF 29 CAPLUS COPYRIGHT 2004 ACS on STN DUPLICATE 4  
 AN 1998:451041 CAPLUS  
 DN 129:136506  
 ED Entered STN: 22 Jul 1998  
 TI  $\pi$ -Conjugated **polymers** bearing electronic and optical functionalities. Preparation, properties and their applications  
 AU Yamamoto, Takakazu; Hayashida, Naoki  
 CS Research Laboratory of Resources Utilization, Tokyo Institute of Technology, Yokohama, 226, Japan  
 SO Reactive & Functional Polymers (1998), 37(1-3), 1-17  
 CODEN: RFPOF6; ISSN: 1381-5148  
 PB Elsevier Science B.V.  
 DT Journal; General Review  
 LA English  
 CC 35-0 (Chemistry of Synthetic High Polymers)  
 Section cross-reference(s): 36, 73, 76  
 AB A review with 54 refs. Various  $\pi$ -conjugated **polymers** are obtained by using organometallic polycondensation mediated by organotransition-metal **complexes**. For example, Ni(O) complex-mediated dehalogenation polycondensation of dihaloarom. compds. XArX affords poly(arylene)s (Ar)<sub>n</sub>. These **polymers** show interesting electronic and optical properties and have already found several useful future applications such as battery, **EL** (**electroluminescence**), diode, nonlinear optical device, etc. In this review, preparation, basic properties and practical applications for **electronic** and optical **devices** of  $\pi$ -conjugated **polymers** were described.  
 ST review conjugated **polymer** prepn organometallic polycondensation; nonlinear optical property conjugated **polymer** review; elec property conjugated **polymer** review; **electroluminescence** conjugated **polymer** review; battery conjugated **polymer** review  
 IT Organometallic compounds  
 RL: CAT (Catalyst use); USES (Uses)  
 (catalyst; preparation, properties and applications of  $\pi$ -Conjugated **polymers** bearing electronic and optical functionalities)  
 IT **Polymers**, preparation  
 RL: MSC (Miscellaneous); PRP (Properties); SPN (Synthetic preparation); **PREP (Preparation)**  
 (conjugated; preparation, properties and applications of  $\pi$ -Conjugated **polymers** bearing electronic and optical functionalities)  
 IT **Polymerization** catalysts  
 (for preparation of  $\pi$ -Conjugated **polymers** bearing electronic and optical functionalities)

IT Conducting polymers  
Electric conductivity  
Luminescence, electroluminescence  
Nonlinear optical materials  
Nonlinear optical properties  
Optical properties  
Polymerization  
(preparation, properties and applications of  $\pi$ -Conjugated polymers bearing electronic and optical functionalities)

IT Polyphenyls  
RL: MSC (Miscellaneous); PRP (Properties); SPN (Synthetic preparation); PREP (Preparation)  
(preparation, properties and applications of  $\pi$ -Conjugated polymers bearing electronic and optical functionalities)

RE.CNT 146 THERE ARE 146 CITED REFERENCES AVAILABLE FOR THIS RECORD

RE

- (1) Adachi, C; Appl Phys Lett 1990, V57, P531 CAPLUS
- (2) Akermack, B; J Am Chem Soc 1979, V101, P5876
- (3) Akermack, B; J Organomet Chem 1978, V149, P97 CAPLUS
- (4) Anon; EP 643118 1995 CAPLUS
- (5) Bochmann, M; J Polym Sci, Part A: Polym Chem 1994, V32, P2493 CAPLUS
- (6) Bradley, D; Synth Met 1993, V54, P401 CAPLUS
- (7) Brown, D; J Electron Mat 1991, V20, P945
- (8) Burroughes, J; Nature 1990, V347, P539 CAPLUS
- (9) Chan, W; Macromolecules 1995, V28, P6410 CAPLUS
- (10) Chen, T; J Am Chem Soc 1995, V117, P233 CAPLUS
- (11) Chiang, J; Synth Met 1986, V13, P193 CAPLUS
- (12) Daifuku, E; Kino Zairyo 1988, V8, P17
- (13) Dieck, H; J Organomet Chem 1975, V93, P259 CAPLUS
- (14) Erdmann, K; J Polym Sci, Part B: Polym Phys 1994, V32, P1961
- (15) Etori, H; Chem Lett 1994, P461 CAPLUS
- (16) Funaki, H; Synth Met 1995, V74, P59 CAPLUS
- (17) Garnier, F; Synth Met 1991, V45, P163 CAPLUS
- (18) Greiner, A; Macromol Chem Phys 1996, V197, P113 CAPLUS
- (19) Heck, R; J Org Chem 1972, V37, P2320 CAPLUS
- (20) Hu, Q; Macromolecules 1996, V29, P5075 CAPLUS
- (21) Iyoda, M; Chem Lett 1985, P127 CAPLUS
- (22) Kanbara, T; Chem Lett 1993, P1459 CAPLUS
- (23) Kanbara, T; J Polym Sci, Part A, Polym Chem 1995, V33, P999 CAPLUS
- (24) Kanbara, T; J Polym Sci, Part A: Polym Chem 1995, V33, P999 CAPLUS
- (25) Kanbara, T; J Power Sources 1991, V36, P87 CAPLUS
- (26) Kanbara, T; Macromolecules 1993, V26, P1975 CAPLUS
- (27) Kende, A; Tetrahedron Lett 1977, P3375
- (28) Kim, Y; J Chem Soc, Dalton 1994, P943 CAPLUS
- (29) Kitada, K; Polym J 1995, V27, P1161 CAPLUS
- (30) Kizu, K; Polym J 1995, V27, P205 CAPLUS
- (31) Kohara, T; J Organomet Chem 1980, V192, P265
- (32) Komiya, S; Organometallics 1983, V2, P1466 CAPLUS
- (33) Kurihara, T; Electronics Lett 1992, V28, P681 CAPLUS
- (34) Liu, C; Polym J 1993, V25, P363 CAPLUS
- (35) Liu, C; Polym J 1993, V25, P775 CAPLUS
- (36) Londa, L; Macromolecules 1997, V30, P1524
- (37) Macdiarmid, A; Chem Eng News 1984, P38
- (38) Macdiarmid, A; Synth Met 1987, V18, P393 CAPLUS
- (39) Macinnes, D; J Chem Soc, Chem Commun 1981, P317 CAPLUS

- (40) Maruyama, T; J Phys Chem B 1997, V101, P3806 CAPLUS
- (41) Matsuda, J; J Chem Soc, Faraday 1995, V91, P1477 CAPLUS
- (42) McCullough, R; J Org Chem 1993, V58, P904 CAPLUS
- (43) Miyamae, T; J Chem Phys 1995, V103, P2738 CAPLUS
- (44) Miyazaki, Y; Synth Met 1994, V64, P69 CAPLUS
- (45) Mizoroki, T; Bull Chem Soc Jpn 1971, V44, P581 CAPLUS
- (46) Moon, D; Chem Lett 1991, P1633 CAPLUS
- (47) Moon, D; Macromolecules 1993, V26, P364 CAPLUS
- (48) Moon, D; Macromolecules 1993, V26, P6992 CAPLUS
- (49) Moon, D; Makromol Chem 1992, V193, P1723 CAPLUS
- (50) Moon, D; Makromol Chem 1993, V194, P3149 CAPLUS
- (51) Muramatsu, Y; Chem Lett 1997, P581 CAPLUS
- (52) Nishide, H; Bull Chem Soc Jpn 1996, V69, P499 CAPLUS
- (53) Ooba, N; Jpn J Appl Phys 1995, V34, P3139 CAPLUS
- (54) Ooba, N; Nonlinear Optics 1996, V15, P481 CAPLUS
- (55) Remmers, M; Macromol Rapid Commun 1996, V17, P239 CAPLUS
- (56) Saito, N; Chem Lett 1993, P1775 CAPLUS
- (57) Saito, N; Macromolecules 1994, V27, P419
- (58) Saito, N; Macromolecules 1994, V27, P756 CAPLUS
- (59) Saito, N; Macromolecules 1995, V28, P4260 CAPLUS
- (60) Saito, N; Macromolecules 1995, V28, P4260 CAPLUS
- (61) Saito, N; Polym Bull 1993, V30, P285 CAPLUS
- (62) Saitoh, Y; Chem Lett 1995, P785 CAPLUS
- (63) Sanechika, K; Bull Chem Soc Jpn 1984, V57, P752 CAPLUS
- (64) Sanechika, K; Polym Prepr Jpn 1979, V27, P966
- (65) Sanechika, K; Polym Prepr Jpn 1981, V30, P160
- (66) Schacklette, L; J Chem Soc, Chem Commun 1982, P361
- (67) Semmelhack, M; J Am Chem Soc 1975, V97, P3873 CAPLUS
- (68) Skotheim, T; Handbook of Conducting Polymers 1986, VI and II
- (69) Sonogashira, K; Tetrahedron Lett 1975, V16, P4467
- (70) Stille, J; Angew Chem, Int Ed Engl 1986, V25, P508
- (71) Suruga, K; Synth Met 1996, V79, P149 CAPLUS
- (72) Suzuki, A; Acc Chem Res 1982, V15, P178 CAPLUS
- (73) Suzuki, A; Pure Appl Chem 1985, V57, P1749 CAPLUS
- (74) Tamao, A; Bull Chem Soc Jpn 1976, V49, P1958
- (75) Tamao, K; Macromolecules 1995, V28, P8668 CAPLUS
- (76) Tatsumi, K; J Am Chem Soc 1984, V106, P8181 CAPLUS
- (77) Tsumura, A; Synth Met 1988, V25, P11 CAPLUS
- (78) Tsumura, A; Synth Met 1991, V41/4, P1181
- (79) Ueda, M; Jpn J Appl Phys 1993, V32, PL921
- (80) Wakabayashi, M; Synth Met 1993, V55/57, P3632
- (81) Wang, Y; Macromolecules 1995, V28, P3495 CAPLUS
- (82) Wolf, M; Chem Mat 1994, V6, P1526 CAPLUS
- (83) Yamamoto, T; JP 47421 1981
- (84) Yamamoto, T; JP 147426 1983
- (85) Yamamoto, T; JP 120926 1984
- (86) Yamamoto, T; JP 1236581 1984
- (87) Yamamoto, T; JP 1258016 1985
- (88) Yamamoto, T; JP 1262404 1985
- (89) Yamamoto, T; US 4521589 1985 CAPLUS
- (90) Yamamoto, T; JP 233014 1986
- (91) Yamamoto, T; US 5310829 1994 CAPLUS
- (92) Yamamoto, T; EP 597234 1994 CAPLUS
- (93) Yamamoto, T; Bull Chem Soc Jpn 1978, V51, P2091 CAPLUS
- (94) Yamamoto, T; Bull Chem Soc Jpn 1983, V56, P1497 CAPLUS

- (95) Yamamoto, T; Chem Ind (London) 1982, P301 CAPLUS
- (96) Yamamoto, T; Chem Lett 1977, P353 CAPLUS
- (97) Yamamoto, T; Chem Lett 1984, P1576
- (98) Yamamoto, T; Chem Lett 1985, P563 CAPLUS
- (99) Yamamoto, T; Chem Lett 1988, P153
- (100) Yamamoto, T; Chem Lett 1990, P223
- (101) Yamamoto, T; Chem Lett 1992, P1003 CAPLUS
- (102) Yamamoto, T; Chem Lett 1993, P1211 CAPLUS
- (103) Yamamoto, T; Chem Lett 1996, P127 CAPLUS
- (104) Yamamoto, T; Chem Lett 1996, P65 CAPLUS
- (105) Yamamoto, T; Chem Lett 1996, P703 CAPLUS
- (106) Yamamoto, T; Chem Lett 1997, P139 CAPLUS
- (107) Yamamoto, T; Chem Mat 1994, V6, P44 CAPLUS
- (108) Yamamoto, T; Chem Mat 1997, V9, P1217 CAPLUS
- (109) Yamamoto, T; Denki Kagaku 1994, V62, P84 CAPLUS
- (110) Yamamoto, T; Inorg Chim Acta 1983, V73f, P75
- (111) Yamamoto, T; J Am Chem Soc 1971, P3360 CAPLUS
- (112) Yamamoto, T; J Am Chem Soc 1980, V93, P3350
- (113) Yamamoto, T; J Am Chem Soc 1994, V116, P4832 CAPLUS
- (114) Yamamoto, T; J Am Chem Soc 1996, V118, P10389 CAPLUS
- (115) Yamamoto, T; J Am Chem Soc 1996, V118, P10389 CAPLUS
- (116) Yamamoto, T; J Am Chem Soc 1996, V118, P3930 CAPLUS
- (117) Yamamoto, T; J Appl Electrochem 1987, V17, P607 CAPLUS
- (118) Yamamoto, T; J Chem Soc, Chem Commun 1981, P187 CAPLUS
- (119) Yamamoto, T; J Chem Soc, Chem Commun 1993, P797 CAPLUS
- (120) Yamamoto, T; J Chem Soc, Chem Commun 1995, P1613 CAPLUS
- (121) Yamamoto, T; J Organomet Chem 1992, V428, P223 CAPLUS
- (122) Yamamoto, T; J Phys Chem 1992, V96, P8677 CAPLUS
- (123) Yamamoto, T; J Phys Chem 1996, V100, P12631 CAPLUS
- (124) Yamamoto, T; J Polym Sci, Part A: Polym Chem 1996, V34, P997 CAPLUS
- (125) Yamamoto, T; J Polym Sci, Polym Lett Ed 1980, V18, P9 CAPLUS
- (126) Yamamoto, T; Jpn J Appl Phys 1994, V33, PL250 CAPLUS
- (127) Yamamoto, T; Kino Zairyo 1995, V15, P39 CAPLUS
- (128) Yamamoto, T; Macromol Chem Phys 1996, V197, P165 CAPLUS
- (129) Yamamoto, T; Macromol Chem Phys 1997, V198, P341 CAPLUS
- (130) Yamamoto, T; Macromolecules 1992, V25, P1214 CAPLUS
- (131) Yamamoto, T; Macromolecules 1992, V25, P1214 CAPLUS
- (132) Yamamoto, T; Macromolecules 1994, V27, P6620 CAPLUS
- (133) Yamamoto, T; Macromolecules 1995, V28, P3371 CAPLUS
- (134) Yamamoto, T; Makromol Chem 1989, V190, P1649 CAPLUS
- (135) Yamamoto, T; Makromol Chem Rapid Commun 1993, V14, P495 CAPLUS
- (136) Yamamoto, T; Makromol Chem, Rapid Commun 1985, V6, P671 CAPLUS
- (137) Yamamoto, T; Makromol Rapid Commun 1995, V16, P549 CAPLUS
- (138) Yamamoto, T; Polym Prepr Jpn 1976, V25, PG2B07
- (139) Yamamoto, T; Polymer 1997, V38, P4233 CAPLUS
- (140) Yamamoto, T; Polymer Battery 1990
- (141) Yamamoto, T; Prog Polym Sci 1992, V17, P1153 CAPLUS
- (142) Yamamoto, T; Synth Met 1990, V38, P399 CAPLUS
- (143) Yaniger, S; Macromolecules 1984, V17, P2579 CAPLUS
- (144) Zembayashi, M; Tetrahedron Lett 1977, P4089 CAPLUS
- (145) Zhou, Z; J Chem Soc, Chem Commun 1991, P1210 CAPLUS
- (146) Zhou, Z; J Organomet Chem 1991, V414, P119 CAPLUS

DNN N1995-107782 DNC C1995-063155  
 TI Crown moiety-containing peptide - useful as detector of sodium and potassium ions, **electronic device** material, etc..  
 DC A23 A89 E34 J04 L03 S03 U11  
 PA (AGEN) AGENCY OF IND SCI & TECHNOLOGY  
 CYC 1  
 PI JP 07062088 A 19950307 (199518)\* 5p C08G069-02  
 JP 2500329 B2 19960529 (199626) 5p C08G069-08  
 ADT JP 07062088 A JP 1991-132233 19910509; JP 2500329 B2 JP 1991-132233 19910509  
 FDT JP 2500329 B2 Previous Publ. JP 07062088  
 PRAI JP 1991-132233 19910509  
 IC ICM C08G069-02; C08G069-08  
 AB JP 07062088 A UPAB: 19970502  
 An aminoacid(s) **polymer** X(NH(CORNH)n-H)m (I) having crown compound residue (II) in the main chain is new. R = opt. substd. 1-10C alkylene; X = crown cpd. residue; m = 1, 2 3; and n = 10-5000. Also claimed is the preparation of (I) comprising (1) **polymerisation** of aminoacid(s) (III) using amino gp(s).-containing crown cpd(s). (IV) as **polymerisation** initiator, or (2) condensation of aminoacid(s) **polymer** HO(CORNH)n-H (V) with crown cpd(s). X(NCO)m (VI).  
 Crown cpds. having phenyl gp(s). substd. with amino gp(s). is used as pref. (IV). Crown cpd(s). having isocyanate gp(s). is used as pref. (VI). (I) is prepared by reaction of NH2RCOOH (III) with X(NH2)m (IV) (pref. aminobenzo-15-crown-5 (IVa)).  
 USE/ADVANTAGE - (I) has affinity to a specific metal ion, and is useful as a detector of a specific metal ion (especially alkali metal ion) and/or agent for quantitative analysis of a specific metal ion, as an **electronic device** material or sensor material, etc. (I) selectively forms **fluorescent complex(es)** with a specific **metal** ion.  
 Dwg.0/1  
 FS CPI EPI  
 FA AB; GI; DCN  
 MC CPI: A05-F03; A10-E17; A12-E13; A12-L04B; E06-H; E07-H; J04-B01B; L03-J  
 EPI: S03-E03; S03-E04D; U11-A09

=>